

DLP390TP 0.39-Inch 4K UHD Digital Micromirror Device

1 Features

- 0.39" diagonal micromirror array
 - 4K UHD (3840 × 2160) display resolution
 - 4.5µm micromirror pitch
 - ±14.5° micromirror tilt (relative to flat surface)
 - Side illumination
- SubLVDS input data bus
- Supports 4K UHD at 60Hz
- Supports 1080p up to 240Hz
- LED operation is supported by DLPC8445V display controller, DLPA3085 / DLPA3082 power management IC (PMIC) and illumination driver

2 Applications

- [Mobile smart TV](#)
- [Mobile projector](#)
- [Digital signage](#)

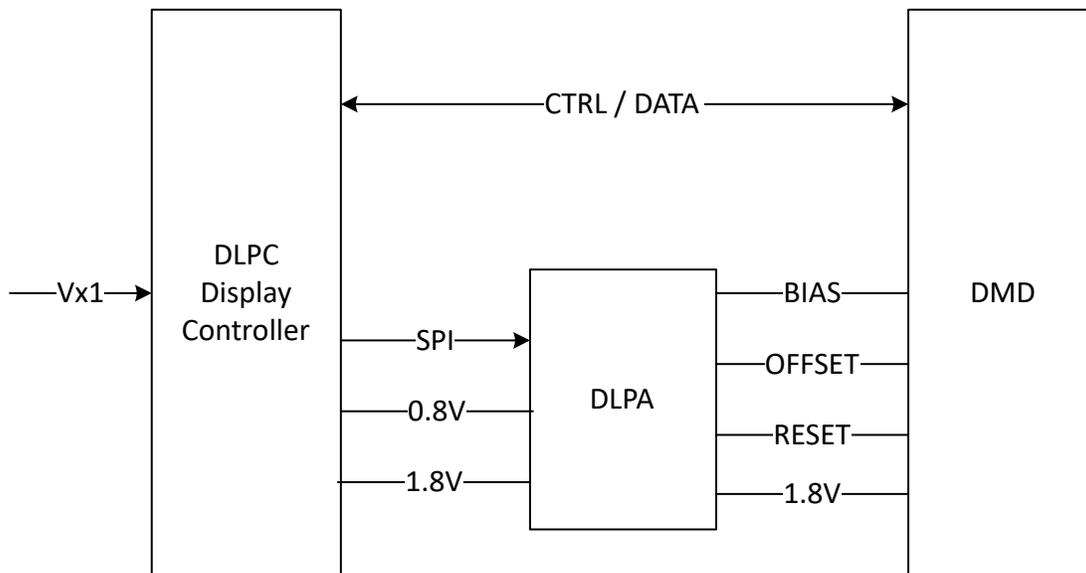
3 Description

The DLP390TP digital micromirror device (DMD) is a digitally controlled micro-electro-mechanical system (MEMS) spatial light modulator (SLM) that enables bright 4K UHD display systems. The TI DLP® Products 0.39" 4K UHD chipset is composed of the DMD, DLPC8445V display controller, and DLPA3085 / DLPA3082 PMIC and illumination driver. The compact physical size of the chipset provides a complete system solution that enables small form factor 4K UHD displays.

Device Information

PART NUMBER	PACKAGE ⁽¹⁾	PACKAGE SIZE
DLP390TP	FQZ (159)	19.25mm × 10.08mm

(1) For more information, see the *Mechanical, Packaging, and Orderable* addendum.



Simplified Application



Table of Contents

1 Features	1	6.6 Micromirror Array Temperature Calculation.....	26
2 Applications	1	6.7 Micromirror Power Density Calculation.....	27
3 Description	1	6.8 Window Aperture Illumination Overfill Calculation....	29
4 Pin Configuration and Functions	3	6.9 Micromirror Landed-On/Landed-Off Duty Cycle.....	30
5 Specifications	8	7 Application and Implementation	33
5.1 Absolute Maximum Ratings.....	8	7.1 Application Information.....	33
5.2 Storage Conditions.....	9	7.2 Typical Application.....	33
5.3 ESD Ratings.....	9	7.3 Temperature Sensor Diode.....	34
5.4 Recommended Operating Conditions.....	10	8 Power Supply Recommendations	35
5.5 Thermal Information.....	13	8.1 DMD Power Supply Power-Up Procedure.....	35
5.6 Electrical Characteristics.....	14	8.2 DMD Power Supply Power-Down Procedure.....	35
5.7 Switching Characteristics.....	15	9 Layout	37
5.8 Timing Requirements.....	15	9.1 Layout Guidelines.....	37
5.9 System Mounting Interface Loads.....	20	10 Device and Documentation Support	38
5.10 Micromirror Array Physical Characteristics.....	21	10.1 Third-Party Products Disclaimer.....	38
5.11 Micromirror Array Optical Characteristics.....	22	10.2 Device Support.....	38
5.12 Window Characteristics.....	23	10.3 Documentation Support.....	39
5.13 Chipset Component Usage Specification.....	23	10.4 Receiving Notification of Documentation Updates..	39
6 Detailed Description	24	10.5 Support Resources.....	39
6.1 Overview.....	24	10.6 Trademarks.....	39
6.2 Functional Block Diagram.....	24	10.7 Electrostatic Discharge Caution.....	39
6.3 Feature Description.....	25	10.8 Glossary.....	39
6.4 Device Functional Modes.....	25	11 Revision History	39
6.5 Optical Interface and System Image Quality Considerations.....	25	12 Mechanical, Packaging, and Orderable Information	40

4 Pin Configuration and Functions

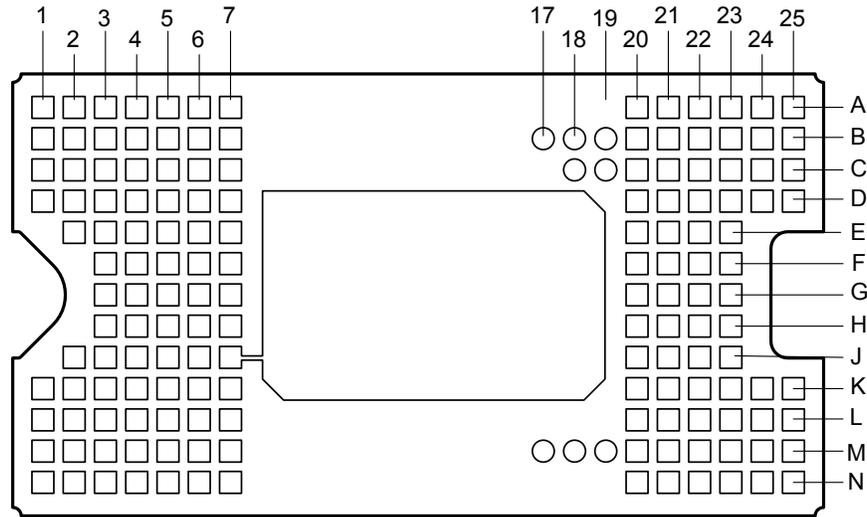


Figure 4-1. FQZ Package 159-Pin LGA (Bottom View)

Table 4-1. Pin Functions

PIN ⁽²⁾		TYPE ⁽¹⁾	DESCRIPTION	TERMINATION	TRACE LENGTH (mm)
NAME	PAD ID				
D_AP(0)	C7	I	High-Speed Differential Data Pair lane A0	Differential 100Ω	3.927
D_AN(0)	D7	I	High-Speed Differential Data Pair lane A0	Differential 100Ω	4.265
D_AP(1)	D5	I	High-Speed Differential Data Pair lane A1	Differential 100Ω	2.565
D_AN(1)	D6	I	High-Speed Differential Data Pair lane A1	Differential 100Ω	2.902
D_AP(2)	E3	I	High-Speed Differential Data Pair lane A2	Differential 100Ω	0.543
D_AN(2)	E4	I	High-Speed Differential Data Pair lane A2	Differential 100Ω	0.881
D_AP(3)	D1	I	High-Speed Differential Data Pair lane A3	Differential 100Ω	2.015
D_AN(3)	D2	I	High-Speed Differential Data Pair lane A3	Differential 100Ω	2.352
D_AP(4)	F6	I	High-Speed Differential Data Pair lane A4	Differential 100Ω	3.19
D_AN(4)	F7	I	High-Speed Differential Data Pair lane A4	Differential 100Ω	3.526
D_AP(5)	F5	I	High-Speed Differential Data Pair lane A5	Differential 100Ω	2.123
D_AN(5)	G5	I	High-Speed Differential Data Pair lane A5	Differential 100Ω	2.456
D_AP(6)	G3	I	High-Speed Differential Data Pair lane A6	Differential 100Ω	0.829
D_AN(6)	G4	I	High-Speed Differential Data Pair lane A6	Differential 100Ω	1.162

Table 4-1. Pin Functions (continued)

PIN ⁽²⁾		TYPE ⁽¹⁾	DESCRIPTION	TERMINATION	TRACE LENGTH (mm)
NAME	PAD ID				
D_AP(7)	H7	I	High-Speed Differential Data Pair lane A7	Differential 100Ω	3.856
D_AN(7)	G7	I	High-Speed Differential Data Pair lane A7	Differential 100Ω	4.189
DCLK_AP	E5	I	High-Speed Differential Clock A	Differential 100Ω	2.23
DCLK_AN	E6	I	High-Speed Differential Clock A	Differential 100Ω	2.562
D_BP(0)	B25	I	High-Speed Differential Data Pair lane B0	Differential 100Ω	2.825
D_BN(0)	B24	I	High-Speed Differential Data Pair lane B0	Differential 100Ω	3.158
D_BP(1)	D25	I	High-Speed Differential Data Pair lane B1	Differential 100Ω	1.636
D_BN(1)	D24	I	High-Speed Differential Data Pair lane B1	Differential 100Ω	1.972
D_BP(2)	D21	I	High-Speed Differential Data Pair lane B2	Differential 100Ω	2.278
D_BN(2)	D20	I	High-Speed Differential Data Pair lane B2	Differential 100Ω	2.611
D_BP(3)	C24	I	High-Speed Differential Data Pair lane B3	Differential 100Ω	3.099
D_BN(3)	C23	I	High-Speed Differential Data Pair lane B3	Differential 100Ω	3.439
D_BP(4)	E21	I	High-Speed Differential Data Pair lane B4	Differential 100Ω	2.687
D_BN(4)	E20	I	High-Speed Differential Data Pair lane B4	Differential 100Ω	3.022
D_BP(5)	F22	I	High-Speed Differential Data Pair lane B5	Differential 100Ω	1.323
D_BN(5)	F21	I	High-Speed Differential Data Pair lane B5	Differential 100Ω	1.658
D_BP(6)	G23	I	High-Speed Differential Data Pair lane B6	Differential 100Ω	0.821
D_BN(6)	G22	I	High-Speed Differential Data Pair lane B6	Differential 100Ω	1.162
D_BP(7)	G21	I	High-Speed Differential Data Pair lane B7	Differential 100Ω	2.173
D_BN(7)	G20	I	High-Speed Differential Data Pair lane B7	Differential 100Ω	2.506
DCLK_BP	E23	I	High-Speed Differential Clock B	Differential 100Ω	0.865
DCLK_BN	E22	I	High-Speed Differential Clock B	Differential 100Ω	1.202
D_CP(0)	J6	I	High-Speed Differential Data Pair lane C0	Differential 100Ω	3.463
D_CN(0)	H6	I	High-Speed Differential Data Pair lane C0	Differential 100Ω	3.795
D_CP(1)	K6	I	High-Speed Differential Data Pair lane C1	Differential 100Ω	3.703
D_CN(1)	K7	I	High-Speed Differential Data Pair lane C1	Differential 100Ω	4.035
D_CP(2)	J2	I	High-Speed Differential Data Pair lane C2	Differential 100Ω	1.461

Table 4-1. Pin Functions (continued)

PIN ⁽²⁾		TYPE ⁽¹⁾	DESCRIPTION	TERMINATION	TRACE LENGTH (mm)
NAME	PAD ID				
D_CN(2)	J3	I	High-Speed Differential Data Pair lane C2	Differential 100Ω	1.759
D_CP(3)	L1	I	High-Speed Differential Data Pair lane C3	Differential 100Ω	2.409
D_CN(3)	K1	I	High-Speed Differential Data Pair lane C3	Differential 100Ω	2.742
D_CP(4)	L6	I	High-Speed Differential Data Pair lane C4	Differential 100Ω	3.15
D_CN(4)	L7	I	High-Speed Differential Data Pair lane C4	Differential 100Ω	3.492
D_CP(5)	N1	I	High-Speed Differential Data Pair lane C5	Differential 100Ω	3.341
D_CN(5)	N2	I	High-Speed Differential Data Pair lane C5	Differential 100Ω	3.679
D_CP(6)	N6	I	High-Speed Differential Data Pair lane C6	Differential 100Ω	3.564
D_CN(6)	N7	I	High-Speed Differential Data Pair lane C6	Differential 100Ω	3.898
D_CP(7)	K2	I	High-Speed Differential Data Pair lane C7	Differential 100Ω	1.022
D_CN(7)	K3	I	High-Speed Differential Data Pair lane C7	Differential 100Ω	1.361
DCLK_CP	M5	I	High-Speed Differential Clock C	Differential 100Ω	3.428
DCLK_CN	L5	I	High-Speed Differential Clock C	Differential 100Ω	3.82
D_DP(0)	H21	I	High-Speed Differential Data Pair lane D0	Differential 100Ω	3.035
D_DN(0)	H20	I	High-Speed Differential Data Pair lane D0	Differential 100Ω	3.369
D_DP(1)	H23	I	High-Speed Differential Data Pair lane D1	Differential 100Ω	0.894
D_DN(1)	H22	I	High-Speed Differential Data Pair lane D1	Differential 100Ω	1.231
D_DP(2)	J22	I	High-Speed Differential Data Pair lane D2	Differential 100Ω	1.791
D_DN(2)	J21	I	High-Speed Differential Data Pair lane D2	Differential 100Ω	2.13
D_DP(3)	K25	I	High-Speed Differential Data Pair lane D3	Differential 100Ω	2.037
D_DN(3)	K24	I	High-Speed Differential Data Pair lane D3	Differential 100Ω	2.372
D_DP(4)	K21	I	High-Speed Differential Data Pair lane D4	Differential 100Ω	2.203
D_DN(4)	K20	I	High-Speed Differential Data Pair lane D4	Differential 100Ω	2.543
D_DP(5)	L25	I	High-Speed Differential Data Pair lane D5	Differential 100Ω	2.72
D_DN(5)	M25	I	High-Speed Differential Data Pair lane D5	Differential 100Ω	3.052
D_DP(6)	N24	I	High-Speed Differential Data Pair lane D6	Differential 100Ω	2.997

Table 4-1. Pin Functions (continued)

PIN ⁽²⁾		TYPE ⁽¹⁾	DESCRIPTION	TERMINATION	TRACE LENGTH (mm)
NAME	PAD ID				
D_DN(6)	N23	I	High-Speed Differential Data Pair lane D6	Differential 100Ω	3.335
D_DP(7)	N21	I	High-Speed Differential Data Pair lane D7	Differential 100Ω	4.046
D_DN(7)	N20	I	High-Speed Differential Data Pair lane D7	Differential 100Ω	4.338
DCLK_DP	L21	I	High-Speed Differential Clock D	Differential 100Ω	3.658
DCLK_DN	L20	I	High-speed Differential Clock D	Differential 100Ω	4.045
MBRST(0)		NC	Mirrormirror voltage for Reset Block 0		6.16289
MBRST(1)		NC	Mirrormirror voltage for Reset Block 1		3.93281
MBRST(2)		NC	Mirrormirror voltage for Reset Block 2		6.10819
MBRST(3)		NC	Mirrormirror voltage for Reset Block 3		3.42259
MBRST(4)		NC	Mirrormirror voltage for Reset Block 4		4.31038
TP0	K23	I	10 HVia Chain		5.71246
TP1	L23	I	2 MVia Chain		4.99283
TP2	M23	I	Humidity Sensor		4.82511
TEMP_N	N4	I	Temp Diode N		1.70894
TEMP_P	N3	I	Temp Diode P		1.7438
LS_RDATA_D	C3	O	LPSDR Output		0.55459
LS_RDATA_C	C1	O	LPSDR Output		1.39057
LS_WDATA	B5	I	LPSDR Input		1.97914
LS_RDATA_B	B2	O	LPSDR Output		0.98339
LS_RDATA_A	A3	O	LPSDR Output		1.42875
LS_CLK	A4	I	LPSDR Input		1.55589
DMD_DEN_ARSTZ	D3	I	ARSTZ	17.5kΩ pulldown	0.9734
VDD	A2, A5, A7, A21, A23, A25, B1, B20, B22, C4, C5, C22, E2, F4, J5, K4, K22, L3, L23, M4, M6, M21, M22, N25	P	Digital Core Supply Voltage		Plane
VBIAS	A6, B21	P	Supply Voltage for Positive Bias of Micromirror reset signal		Plane
VRESET	B6, C21	P	Supply Voltage for Negative Bias of Micromirror reset signal		Plane
VOFFSET	C6, L22	P	Supply voltage for HVCMOS logic,stepped up logic level		Plane
VDDI	B3, B23, K23, M1, M3, M24	P			Plane

Table 4-1. Pin Functions (continued)

PIN ⁽²⁾		TYPE ⁽¹⁾	DESCRIPTION	TERMINATION	TRACE LENGTH (mm)
NAME	PAD ID				
VSS	A1, A20, A22, A24, B4, B7, C2, C20, C25, D4, D22, D23, E7, F3, F20, F23, G6, H3, H4, H5, J4, J7, J20, J23, K5, L2, L4, L24, M2, M7, M20, M23, N5, N22	G	Ground		Plane
N/C	B17, C18, B18, C19, B19, M17, M19, M18	NC	No Connect Pin		None

(1) I=Input, O=Output, P=Power, G=Ground, NC=No Connect

(2) Only 143 pins are electrically connected for functional use.

5 Specifications

5.1 Absolute Maximum Ratings

PARAMETER	DESCRIPTION	MIN ⁽¹⁾	MAX ⁽¹⁾	UNIT
SUPPLY VOLTAGE				
V _{DD}	Supply voltage for LVCMOS core logic and LPSDR low-speed interface (LSIF) ⁽²⁾	-0.5	2.3	V
V _{DDI}	Supply voltage for SubLVDS receivers ⁽²⁾	-0.5	2.3	V
V _{OFFSET}	Supply voltage for HVCMOS and micromirror electrode ^{(2) (3)}	-0.5	11	V
V _{BIAS}	Supply voltage for micromirror electrode ⁽²⁾	-0.5	19	V
V _{RESET}	Supply voltage for micromirror electrode ⁽²⁾	-15	0.5	V
V _{DDI} - V _{DD}	Supply voltage delta (absolute value) ⁽⁴⁾		0.3	V
V _{BIAS} - V _{OFFSET}	Supply voltage delta (absolute value) ⁽⁵⁾		11	V
V _{BIAS} - V _{RESET}	Supply voltage delta (absolute value) ⁽⁶⁾		34	V
INPUT VOLTAGE				
	Input voltage for other inputs – LSIF and LVCMOS ⁽²⁾	-0.5	V _{DD} +0.5	V
	Input voltage for other inputs – SubLVDS ^{(2) (7)}	-0.5	V _{DDI} +0.5	V
SUBLVDS INTERFACE (HSIF)				
V _{ID}	SubLVDS differential input voltage (absolute value) ⁽⁷⁾		810	mV
I _{ID}	SubLVDS input differential current ⁽⁷⁾		10	mA
CLOCK FREQUENCY				
f _{CLOCK}	LSIF clock frequency (LS_CLK)	100	130	MHz
TEMPERATURE DIODE				
I _{TEMP_DIODE}	Max current source into temperature diode		120	μA
ENVIRONMENTAL				
T _{ARRAY}	Temperature, operating ⁽⁸⁾	0	90	°C
	Temperature, non-operating ⁽⁸⁾	-40	90	°C
T _{DP}	Dew point temperature, operating and non-operating (non-condensing)		81	°C

- (1) Operation outside the Absolute Maximum Ratings may cause permanent device damage. Absolute Maximum Ratings do not imply functional operation of the device at these or any other conditions beyond those listed under Recommended Operating Conditions. If outside the Recommended Operating Conditions but within the Absolute Maximum Ratings, the device may not be fully functional, which may affect device reliability, functionality, and performance, and shorten the device's lifetime.
- (2) All voltage values are concerning the ground terminals (V_{SS}). The following required power supplies must be connected for proper DMD operation: V_{DD}, V_{DDI}, V_{OFFSET}, V_{BIAS}, and V_{RESET}. All V_{SS} connections are also required.
- (3) V_{OFFSET} supply transients must fall within specified voltages.
- (4) Exceeding the recommended allowable absolute voltage difference between V_{DDI} and V_{DD} can result in excessive current draw.
- (5) Exceeding the recommended allowable absolute voltage difference between V_{BIAS} and V_{OFFSET} can result in excessive current draw.
- (6) Exceeding the recommended allowable absolute voltage difference between V_{BIAS} and V_{RESET} can result in excessive current draw.
- (7) This maximum input voltage rating applies when each input of a differential pair is at the same voltage potential. SubLVDS differential inputs must not exceed the specified limit or damage can result to the internal termination resistors.
- (8) The array temperature cannot be measured directly and must be computed analytically from the temperature measured at test point 1 (TP1) shown in [Figure 6-2](#) using the [Micromirror Array Temperature Calculation](#).

5.2 Storage Conditions

Applicable for the DMD as a component or non-operating in a system.

PARAMETER	DESCRIPTION	MIN	MAX	UNIT
T _{DMD}	DMD temperature	–40	85	°C
T _{DP-AVG}	Average dew point temperature, non-condensing ⁽¹⁾		28	°C
T _{DP-ELR}	Elevated dew point temperature range, non-condensing ⁽²⁾	28	36	°C
CT _{ELR}	Cumulative time in elevated dew point temperature range		24	months

- (1) The average temperature over time (including storage and operating temperatures) that the device is not in the elevated dew point temperature range.
- (2) Exposure to dew point temperatures in the elevated range during storage and operation must be limited to less than a total cumulative time of CT_{ELR}.

5.3 ESD Ratings

PARAMETER DESCRIPTION		VALUE	UNIT	
V _(ESD)	Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾	±1000	V
		Charged device model (CDM), per JEDEC specification JESD22C101 ⁽²⁾	±250	V

- (1) JEDEC document JEP155 states that 500V HBM allows safe manufacturing with a standard ESD control process.
- (2) JEDEC document JEP157 states that 250V CDM allows safe manufacturing with a standard ESD control process.

5.4 Recommended Operating Conditions

Over operating free-air temperature range and supply voltages (unless otherwise noted). The functional performance of the device specified in this data sheet is achieved when operating the device within the limits defined by the Recommended Operating Conditions. No level of performance is implied when operating the device above or below the Recommended Operating Conditions limits

PARAMETER	DESCRIPTION	MIN	TYP	MAX	UNIT
SUPPLY VOLTAGE RANGE					
V _{DD}	Supply voltage for LVCMOS core logic ^{(1) (2)} Supply voltage for LPSDR low-speed interface	1.71	1.8	1.95	V
V _{DDI}	Supply voltage for SubLVDS receivers ^{(1) (2)}	1.71	1.8	1.95	V
V _{OFFSET}	Supply voltage for HVCMOS and micromirror electrode ^{(1) (2) (3)}	9.5	10	10.5	V
V _{BIAS}	Supply voltage for mirror electrode ^{(1) (2)}	17.5	18	18.5	V
V _{RESET}	Supply voltage for micromirror electrode ^{(1) (2)}	-14.5	-14	-13.5	V
V _{DDI} - V _{DD}	Supply voltage delta (absolute value) ^{(1) (2) (4)}			0.3	V
V _{BIAS} - V _{OFFSET}	Supply voltage delta (absolute value) ^{(1) (2) (5)}			10.5	V
V _{BIAS} - V _{RESET}	Supply voltage delta (absolute value) ^{(1) (2) (6)}			33	V
LPSDR INTERFACE					
V _{IH}	High-level input voltage	0.7 × V _{DD}			V
V _{IL}	Low-level input voltage	0.3 × V _{DD}			V
V _{IH} (AC)	AC input high voltage	0.8 × V _{DD}			V
V _{IL} (AC)	AC input low voltage	-0.3			V
V _{Hyst}	Input Hysteresis	0.1 × V _{DD}			V
f _{max_LS}	Clock frequency for low speed interface LS_CLK ⁽⁷⁾	108		130	MHz
D _{CDIN}	LSIF duty cycle distortion (LS_CLK) ⁽⁷⁾	44		56	%
SUBLVDS INTERFACE					
V _{ID}	LVDS differential input voltage magnitude ⁽⁸⁾	150	250	350	mV
V _{CM}	Common mode voltage ⁽⁸⁾	700	900	1100	mV
V _{SUBLVDS}	SubLVDS voltage ⁽⁸⁾	525		1275	mV
Z _{LINE}	Line differential impedance (PWB/trace)	90	100	110	Ω
Z _{IN}	Internal differential termination resistance ⁽¹⁰⁾	80	100	120	Ω
TEMPERATURE DIODE					
I _{TEMP_DIODE}	Max current source into Temperature Diode			120	μA
ENVIRONMENTAL					
T _{ARRAY}	Array temperature, long-term operation ^{(9) (10) (11) (12)}	0		40 to 70	°C
T _{DP-AVG}	Average dew point temperature, (non-condensing) ⁽¹³⁾			28	°C
T _{DP-ELR}	Elevated dew point temperature range, (non-condensing) ⁽¹⁴⁾		28	36	°C
C _{T_{ELR}}	Cumulative time in elevated dew point temperature range			24	Months
Q _{AP-LL}	Window Aperture illumination overfill ^{(15) (16) (17)}			17	W/cm ²
ILLUMINATION LPCW, RGB Laser and LED					
ILL _{UV}	Illumination, wavelength < 410nm ^{(9) (19)}			10	mW/cm ²
ILL _{VIS}	Illumination power at wavelengths ≥ 410nm and ≤ 800nm ^{(18) (19)}			40	W/cm ²
ILL _{IR}	Illumination, wavelength between > 800nm ⁽¹⁹⁾			10	mW/cm ²
ILL _{BLU}	Illumination power at wavelengths ≥ 410nm and ≤ 475nm ^{(18) (19)}			12.8	W/cm ²
ILL _{BLU1}	Illumination power at wavelengths ≥ 410nm and ≤ 440nm ^{(18) (19)}			2.0	W/cm ²

- (1) The following power supplies are required to operate the DMD: V_{DD}, V_{DDI}, V_{OFFSET}, V_{BIAS}, and V_{RESET}. All V_{SS} connections are required to operate the DMD.
- (2) All voltage values are with respect to the V_{SS} ground pins.
- (3) V_{OFFSET} supply transients must fall within the specified max voltages.
- (4) To prevent excess current, the supply voltage delta |V_{DDI} - V_{DD}| must be less than the specified limit.

- (5) To prevent excess current, the supply voltage delta $|V_{BIAS} - V_{OFFSET}|$ must be less than the specified limit.
- (6) To prevent excess current, the supply voltage delta $|V_{BIAS} - V_{RESET}|$ must be less than the specified limit.
- (7) LS_CLK must run as specified to meet internal DMD timing for reset waveform commands.
- (8) Refer to the SubLVDS timing requirements in *Timing Requirements*.
- (9) Simultaneous exposure of the DMD to the maximum Recommended Operating Conditions for temperature and UV illumination reduces device lifetime.
- (10) The array temperature cannot be measured directly and must be computed analytically from the temperature measured at test point (TP1) shown in [Figure 6-2](#) and the package thermal resistance using the [Micromirror Array Temperature Calculation](#)
- (11) Long-term is defined as the usable life of the device.
- (12) Per [Figure 5-1](#), the maximum operational array temperature is derated based on the micromirror landed duty cycle that the DMD experiences in the end application. See [Micromirror Landed-on/Landed-off Duty cycle](#) for a definition of micromirror landed duty cycle.
- (13) The average over time (including storage and operating) is that the device is not in the elevated dew point temperature range.
- (14) Exposure to dew point temperatures in the elevated range during storage and operation is limited to less than a total cumulative time of CT_{ELR} .
- (15) Applies to the region defined in [Figure 5-2](#)
- (16) The active area of the DMD is surrounded by an aperture on the inside of the DMD window surface that masks structures of the DMD device assembly for normal view. The aperture is sized to anticipate several optical conditions. Overfill light illuminating the area outside the active array can scatter and create adverse effects on the performance of an end application using the DMD. Minimizing the light flux incident outside the active array is a design requirement of the illumination optical system. Depending on the particular optical architecture and assembly tolerances of the optical system, the amount of overfill light on the outside of the active array may cause system performance degradation.
- (17) To calculate, see [Window Aperture Illumination Overfill Calculation](#).
- (18) The maximum allowable optical power incident on the DMD is limited by the maximum optical power density for each wavelength range specified and the micromirror array temperature (T_{ARRAY}).
- (19) To calculate, see [Micromirror Power Density Calculation](#).

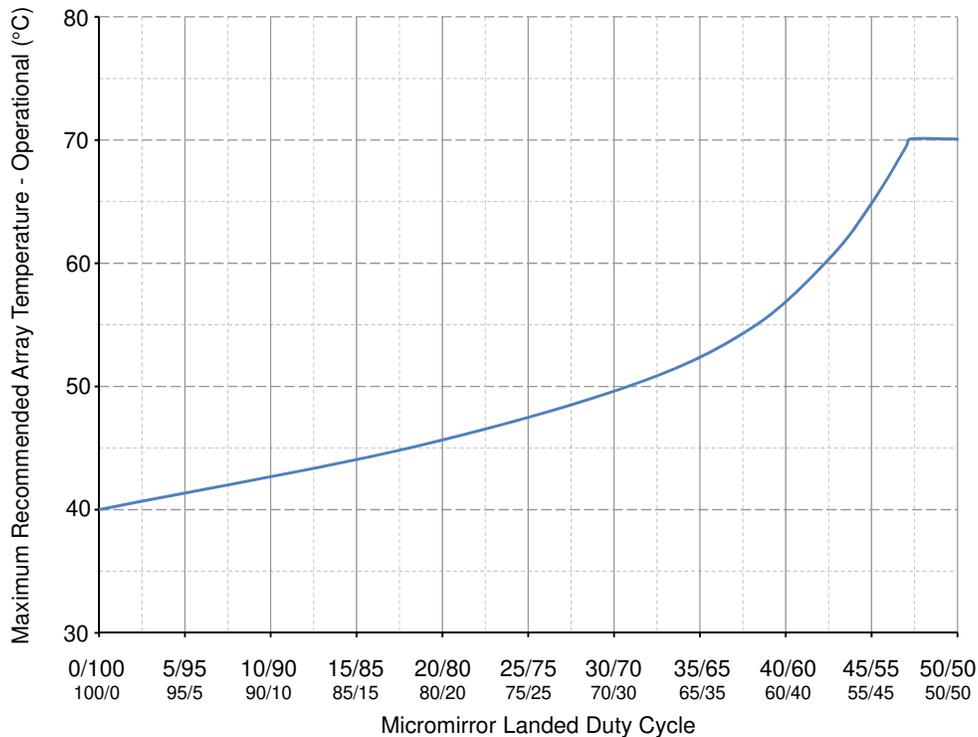


Figure 5-1. Maximum Recommended Array Temperature—Derating Curve

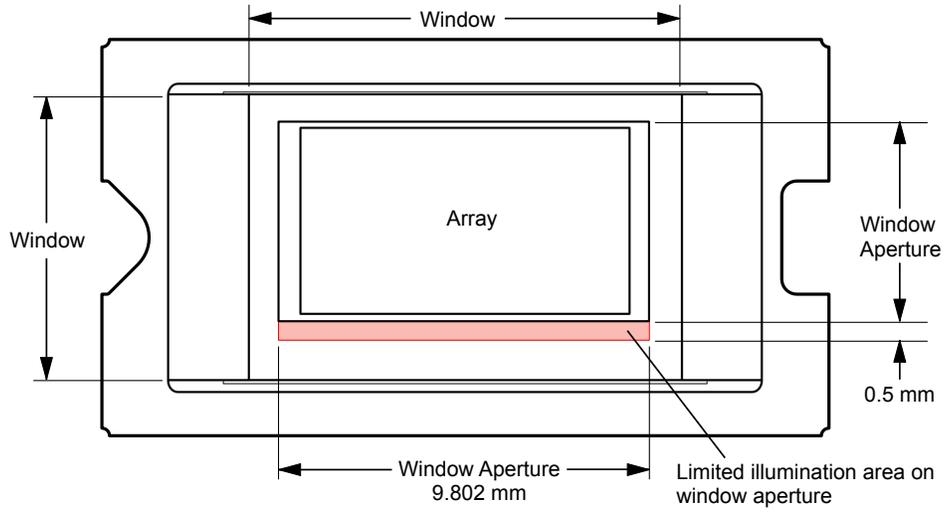


Figure 5-2. Illumination Overfill Diagram—Critical Area

5.5 Thermal Information

THERMAL METRIC	DLP390TP	UNIT
	FQZ	
	159 PIN	
THERMAL INFORMATION		
Thermal Resistance ⁽¹⁾	2	°C/W

- (1) The DMD is designed to conduct absorbed and dissipated heat to the back of the package. The cooling system must be capable of maintaining the DMD within the temperature range specified in the Recommended Operating Conditions. The total heat load on the DMD is largely driven by the incident light absorbed by the active area; although other contributions include light energy absorbed by the window aperture and electrical power dissipation of the array. Optical systems should be designed to minimize the light energy falling outside the window clear aperture since any additional thermal load in this area can significantly degrade the reliability of the device.

5.6 Electrical Characteristics

Over operating free-air temperature range (unless otherwise noted) ⁽¹⁾

PARAMETER ⁽⁶⁾		TEST CONDITIONS ⁽²⁾	MIN	TYP	MAX	UNIT
CURRENT						
I_{DD}	Supply current: V_{DD} ^{(3) (4)}	Typical			140	mA
I_{DDI}	Supply current: V_{DDI} ^{(3) (4)}	Typical			45	mA
I_{OFFSET}	Supply current: V_{OFFSET} ⁽⁵⁾	Typical			6	mA
I_{BIAS}	Supply current: V_{BIAS} ⁽⁵⁾	Typical			0.6	mA
I_{RESET}	Supply current: V_{RESET}	Typical			1.8	mA
POWER						
P_{DD}	Supply power dissipation: V_{DD} ^{(3) (4)}	Typical			252	mW
P_{DDI}	Supply power dissipation: V_{DDI} ^{(3) (4)}	Typical			81	mW
P_{OFFSET}	Supply power dissipation: V_{OFFSET} ⁽⁵⁾	Typical			60	mW
P_{BIAS}	Supply power dissipation: V_{BIAS} ⁽⁵⁾	Typical			1.08	mW
P_{RESET}	Supply power dissipation: V_{RESET}	Typical			25.2	mW
P_{TOTAL}	Supply power dissipation Total	Typical			419.28	mW
LPSDR INPUT						
I_{IL}	Low level input current	$V_{DD} = 1.95V, V_I = 0V$	-100			nA
I_{IH}	High level input current	$V_{DD} = 1.95V, V_I = 1.95V$			135	μA
LPSDR OUTPUT						
V_{OH}	DC output high voltage ^{(7) (8) (9)}	$I_{OH} = -2mA$	$0.8 \times V_{DD}$			X V_{DD}
V_{OL}	DC output low voltage ^{(7) (8) (9)}	$I_{OL} = 2mA$		$0.2 \times V_{DD}$		X V_{DD}
CAPACITANCE						
C_{IN}	Input capacitance LVCMOS	$F = 1MHz$			10	pF
C_{IN}	Input capacitance SubLVDS	$F = 1MHz$			20	pF
C_{OUT}	Output capacitance	$F = 1MHz$			10	pF
C_{TEMP}	Temperature sense diode capacitance	$F = 1MHz$			20	pF

(1) Device electrical characteristics are over [Section 5.4](#) unless otherwise noted.

(2) All voltage values are with respect to the ground pins (V_{SS}).

(3) To prevent excess current, the supply voltage delta $|V_{DDI} - V_{DD}|$ must be less than the specified limit.

(4) Supply power dissipation based on non-compressed commands and data.

(5) To prevent excess current, the supply voltage delta $|V_{BIAS} - V_{OFFSET}|$ must be less than the specified limit.

(6) All power supply connections are required to operate the DMD: V_{DD} , V_{DDI} , V_{OFFSET} , V_{BIAS} , V_{RESET} . All V_{SS} connections are also required.

(7) LPSDR specifications are for pins LS_CLK and LS_WDATA.

(8) Low-speed interface is LPSDR and adheres to the Electrical Characteristics and AC/DC Operating Conditions table in JEDEC Standard No. 209B, Low-Power Double Data Rate (LPDDR) [JESD209B](#).

(9) LPSDR output specification is for pins LS_RDATA_A, LS_RDATA_B, LS_RDATA_C, LS_RDATA_D.

5.7 Switching Characteristics

Over operating free-air temperature range and supply voltages (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
t_{PD}	Output propagation, clock to Q, rising edge of LS_CLK input to LS_RDATA output ⁽¹⁾	$C_L = 45\text{pF}$			15	ns
	Slew rate, LS_RDATA		0.3			V/ns
	Output duty cycle distortion, LS_RDATA_A and LS_RDATA_B		40%		60%	

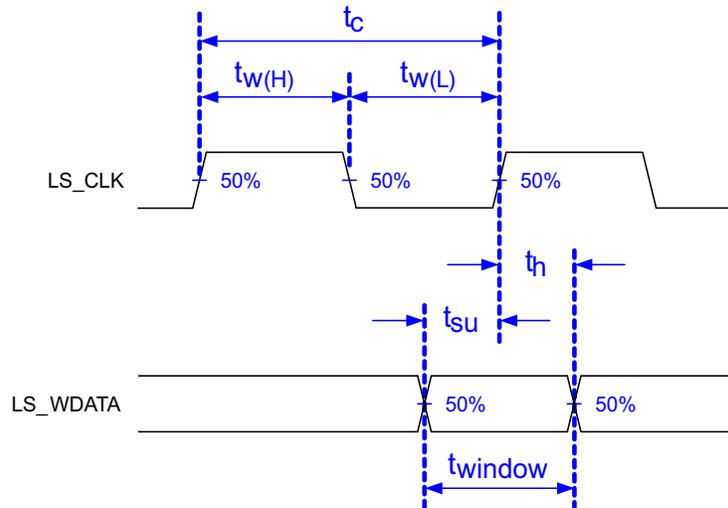
(1) Device electrical characteristics are over [Recommended Operating Conditions](#) unless otherwise noted.

5.8 Timing Requirements

Over operating free-air temperature range and supply voltages (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
LPSDR						
t_r	Rise slew rate ⁽²⁾	$(20\% \text{ to } 80\%) \times V_{DD}$ ⁽⁵⁾	0.25			V/ns
t_f	Fall slew rate ⁽²⁾	$(80\% \text{ to } 20\%) \times V_{DD}$ ⁽⁵⁾	0.25			V/ns
t_r	Rise slew rate ⁽¹⁾	$(30\% \text{ to } 80\%) \times V_{DD}$ ⁽⁵⁾	1		3	V/ns
t_f	Fall slew rate ⁽¹⁾	$(70\% \text{ to } 20\%) \times V_{DD}$ ⁽⁵⁾	1		3	V/ns
$t_{W(H)}$	Pulse duration LS_CLK high	50% to 50% reference points ⁽⁴⁾	4.2			ns
$t_{W(L)}$	Pulse duration LS_CLK low	50% to 50% reference points ⁽⁴⁾	4.2			ns
t_{su}	Setup time	LS_WDATA valid before LS_CLK ⁽⁴⁾			1.5	ns
t_h	Hold time	LS_WDATA valid after LS_CLK ⁽⁴⁾			1.5	ns
SubLVDS						
t_r	Rise slew rate	20% to 80% reference points ⁽⁶⁾	0.7	1		V/ns
t_f	Fall slew rate	80% to 20% reference points ⁽⁶⁾	0.7	1		V/ns
$t_{W(H)}$	Pulse duration DCLK high	50% to 50% reference points ⁽⁷⁾	0.7			ns
$t_{W(L)}$	Pulse duration DCLK low	50% to 50% reference points ⁽⁷⁾	0.7			ns
t_{su}	Setup time	DATA valid before D_CLK ⁽⁷⁾			0.17	ns
t_h	Hold time	DATA valid after D_CLK ⁽⁷⁾			0.17	ns
t_{POWER}	Power-up receiver ⁽³⁾				200	ns

- (1) The specification is for the DMD_DEN_ARSTZ pin. Refer to the LPSDR input rise and fall slew rate in [Figure 5-4](#).
- (2) The specification is for the LS_CLK and LS_WDATA pins. Refer to the LPSDR input rise and fall slew rate in [Figure 5-4](#).
- (3) The specification is for SubLVDS receiver time only and does not take into account commanding and latency after commanding.
- (4) See [Figure 5-3](#).
- (5) See [Figure 5-4](#).
- (6) See [Figure 5-5](#).
- (7) See [Figure 5-7](#).



The low-speed interface is LPSDR and adheres to the Electrical Characteristics and AC/DC Operating Conditions table in JEDEC Standard No. 209B, *Low Power Double Data Rate (LPDDR) JESD209B*.

Figure 5-3. LPSDR Switching Parameters

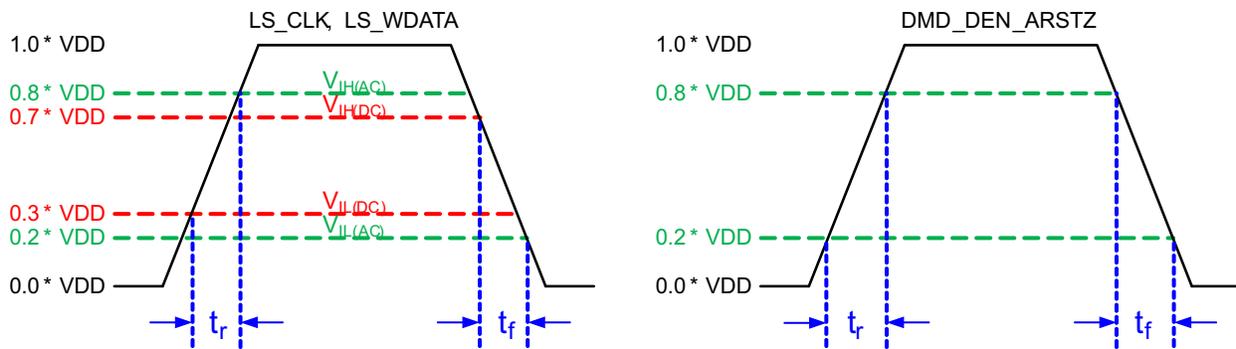


Figure 5-4. LPSDR Input Rise and Fall Slew Rate

Not to Scale

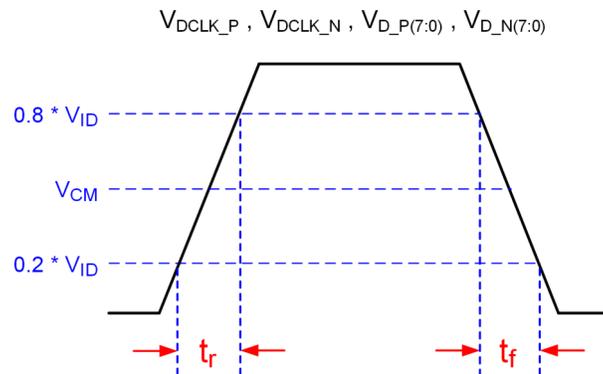


Figure 5-5. SubLVDS Input Rise and Fall Slew Rate

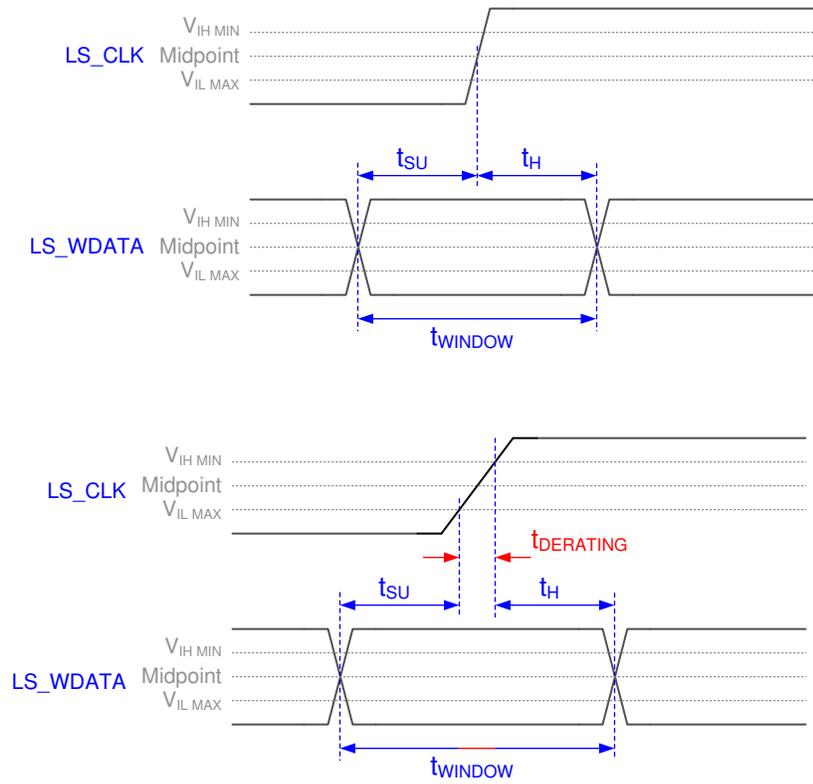


Figure 5-6. Window Time Derating Concept

Not to Scale

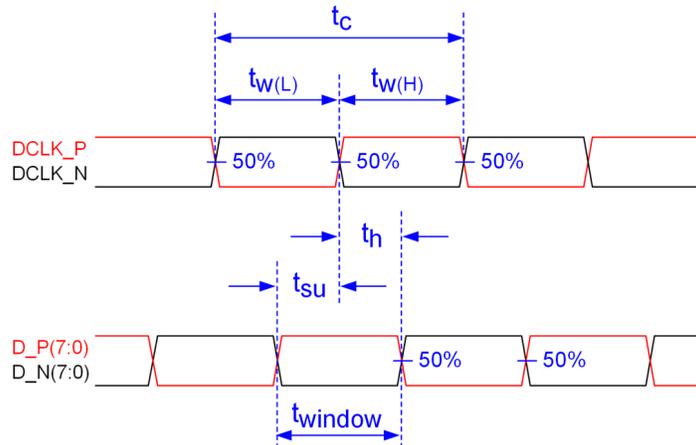
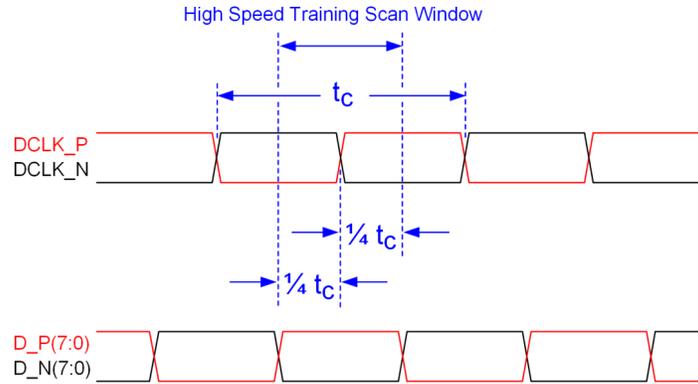


Figure 5-7. SubLVDS Switching Parameters



Refer to *Timing Requirements* for details.

Figure 5-8. High-Speed Training Scan Window

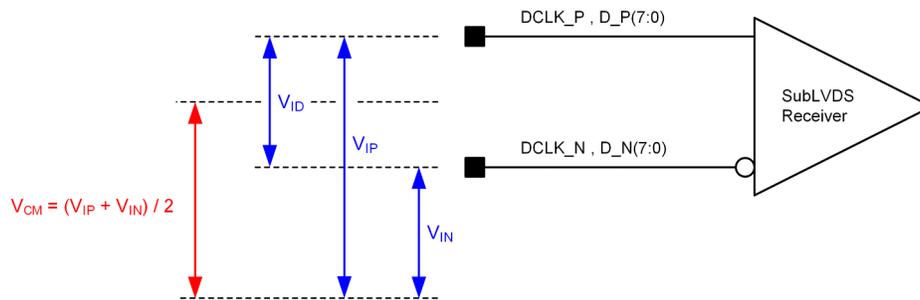


Figure 5-9. SubLVDS Voltage Parameters

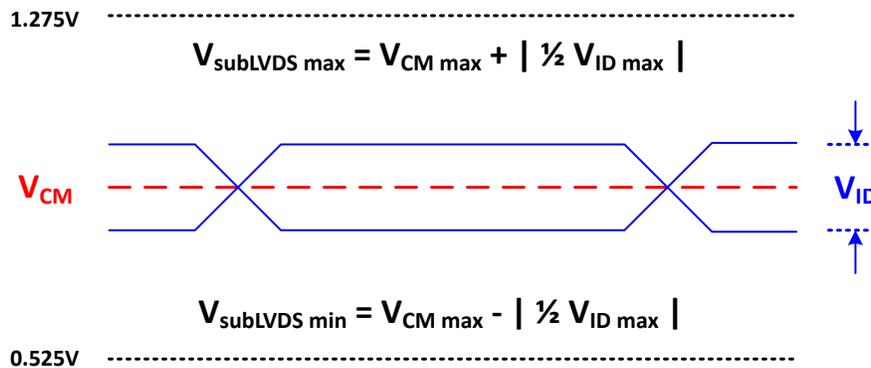


Figure 5-10. SubLVDS Waveform Parameters

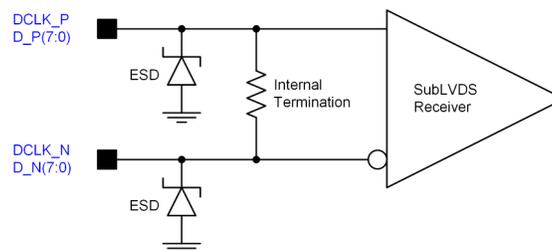


Figure 5-11. SubLVDS Equivalent Input Circuit

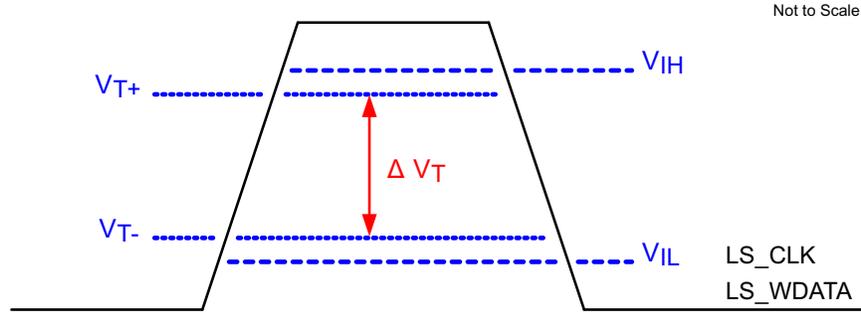


Figure 5-12. LPSDR Input Hysteresis

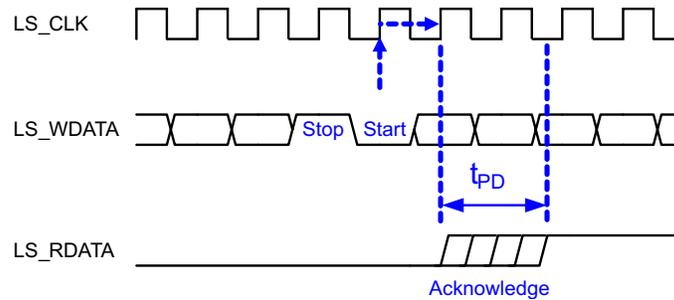
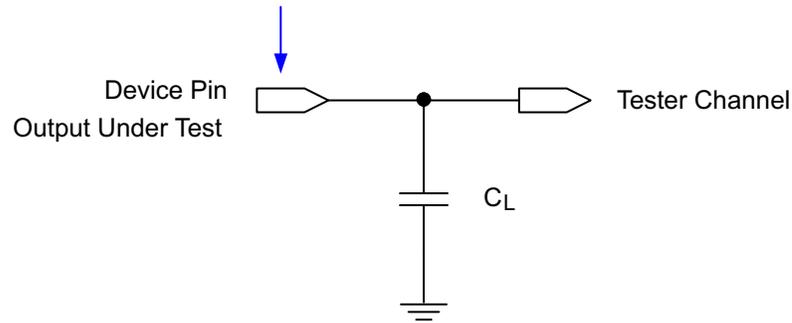


Figure 5-13. LPSDR Read Out

Data Sheet Timing Reference Point



See [Section 6.3.4](#) for more information.

Figure 5-14. Test Load Circuit for Output Propagation Measurement

5.9 System Mounting Interface Loads

PARAMETER	CONDITION	MIN	TYP	MAX	UNIT
Thermal Interface Area	Maximum load evenly distributed within each area ⁽¹⁾			50	N
Electrical Interface Area	Maximum load evenly distributed within each area ⁽¹⁾			143	

(1) See [Figure 5-15](#).

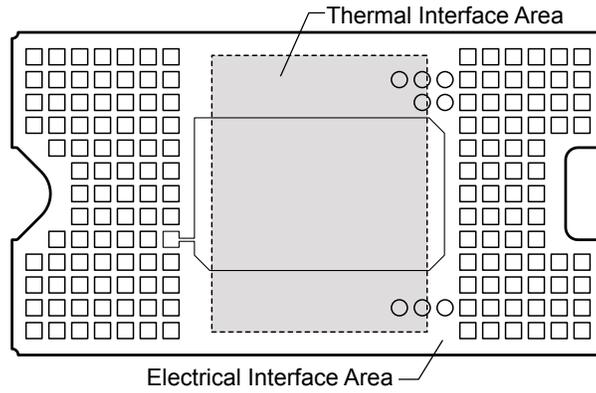


Figure 5-15. System Mounting Interface Loads

5.10 Micromirror Array Physical Characteristics

PARAMETER	DESCRIPTION		VALUE	UNIT
M	Number of active columns ⁽¹⁾ ⁽²⁾		1360	micromirrors
N	Number of active rows ⁽¹⁾ ⁽²⁾		1536	micromirrors
ϵ	Micromirror pitch, diagonal ⁽¹⁾		4.525	μm
P	Micromirror pitch, vertical and horizontal ⁽¹⁾		6.4	μm
	Micromirror active array width ⁽¹⁾	$(P \times M) + (P / 2)$	8.7072	mm
	Micromirror active array height ⁽¹⁾	$(P \times N) / 2 + (P / 2)$	4.9184	mm
	Micromirror active border ⁽³⁾	Pond of micromirror (POM)	15	micromirrors/side

- (1) See [Figure 5-16](#).
- (2) The fast switching speed of the DMD micromirrors combined with advanced DLP image processing algorithms enables each micromirror to display four distinct pixels on the screen during every frame, resulting in a full 3840 x 2160 pixel image being displayed.
- (3) The structure and qualities of the border around the active array include a band of partially functional micromirrors referred to as the *Pond of Micromirrors* (POM). These micromirrors are structurally and/or electrically prevented from tilting toward the bright or ON state but still require an electrical bias to tilt toward the OFF state.

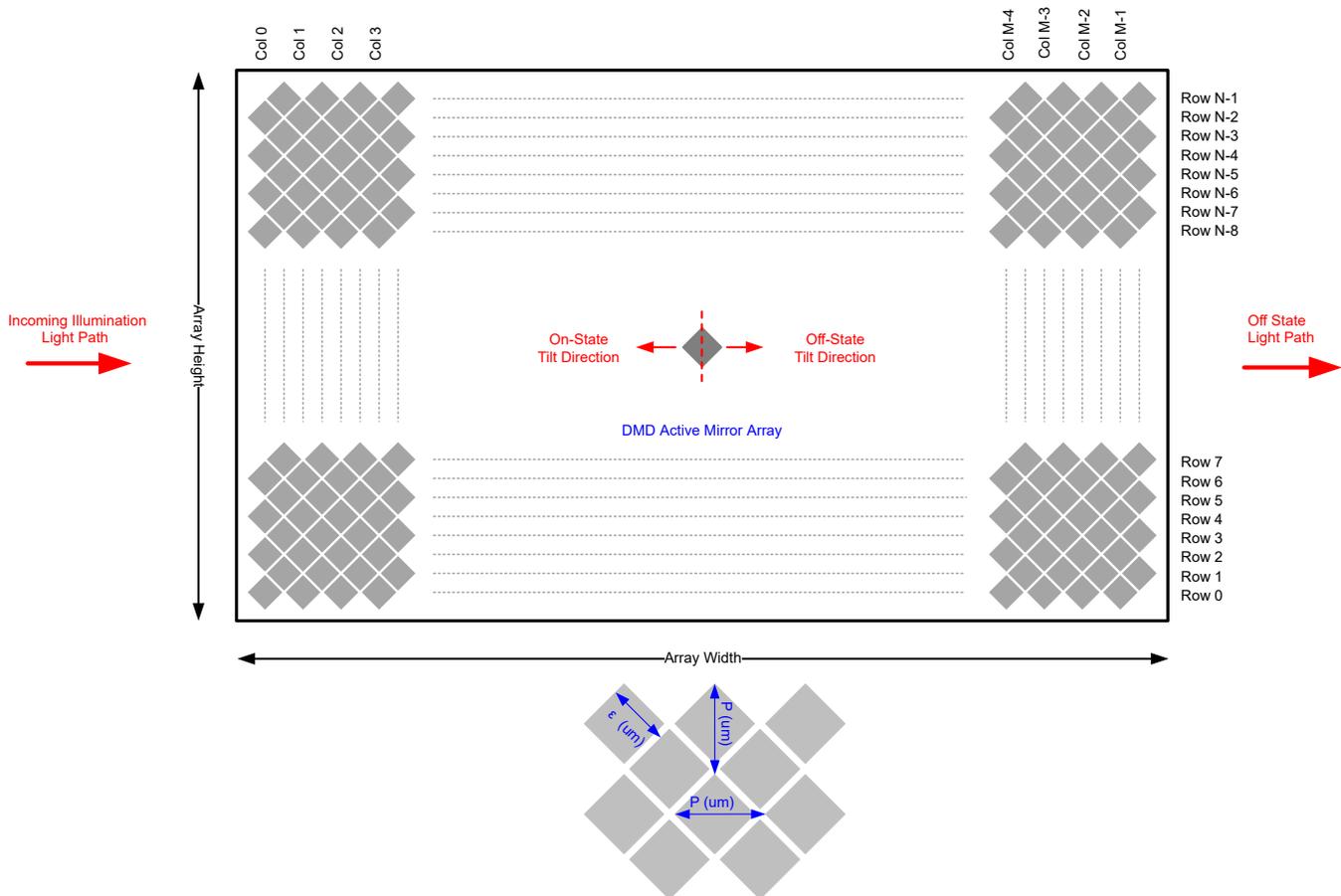


Figure 5-16. Micromirror Array Physical Characteristics

5.11 Micromirror Array Optical Characteristics

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
Micromirror tilt angle		DMD landed state ⁽¹⁾ ⁽²⁾ ⁽³⁾ ⁽⁴⁾	13.5	14.5	15.5	degrees
Micromirror crossover time ⁽⁵⁾				1	3	μs
Micromirror switching time ⁽⁶⁾			6			μs
Image Performance ⁽⁷⁾	Bright pixel(s) in active area ⁽⁸⁾	Gray 10 Screen ⁽⁹⁾			0	Micromirrors
	Bright pixel(s) in the POM ⁽¹⁰⁾	Gray 10 Screen ⁽⁹⁾			1	
	Dark pixel(s) in the active area ⁽¹¹⁾	White Screen			4	
	Adjacent pixel(s) ⁽¹²⁾	Any Screen			0	
	Unstable pixel(s) in active area ⁽¹³⁾	Any Screen			0	

- (1) Measured relative to the plane formed by the overall micromirror array
- (2) Additional variation exists between the micromirror array and the package datums.
- (3) Represents the variation that can occur between any two individual micromirrors, located on the same device or on different devices.
- (4) For some applications, it is critical to account for the micromirror tilt angle variation in the overall system optical design. With some system optical designs, the micromirror tilt angle variation within a device may result in perceivable non-uniformities in the light field reflected from the micromirror array. With some system optical designs, the micromirror tilt angle variation between devices may result in colorimetry variations, system efficiency variations, or system contrast variations.
- (5) The time required for a micromirror to nominally transition from one landed state to the opposite landed state.
- (6) The minimum time between successive transitions of a micromirror
- (7) Conditions of Acceptance: All DMD image quality returns will be evaluated using the following projected image test conditions:
 Test set degamma shall be linear
 Test set brightness and contrast shall be set to nominal
 The diagonal size of the projected image shall be a minimum of 20 inches
 The projection screen shall be unity gain
 The projected image shall be inspected from a 38-inch minimum viewing distance
 The image must be in focus during all image quality tests.
- (8) Bright pixel definition: A single pixel or mirror that is stuck in the ON position and is visibly brighter than the surrounding pixels.
- (9) Gray 10 screen definition: All areas of the screen are colored with the following settings:
 Red = 10/255
 Green = 10/255
 Blue = 10/255
- (10) POM definition: Rectangular border of off-state mirrors surrounding the active area
- (11) Dark pixel definition: A single pixel or mirror that is stuck in the OFF position and is visibly darker than the surrounding pixels.
- (12) Adjacent pixel definition: Two or more stuck pixels sharing a common border or common point, also referred to as a cluster.
- (13) Unstable pixel definition: A single pixel or mirror that does not operate in sequence with parameters loaded into memory. The unstable pixel appears to be flickering asynchronously with the image.

5.12 Window Characteristics

DESCRIPTION ⁽¹⁾		MIN	TYP	MAX
Window material			Corning Eagle XG	
Window refractive index	At wavelength 546.1nm		1.5119	
Window aperture ⁽¹⁾				
Illumination overfill			See Section 6.5	

(1) See the mechanical package ICD for details regarding the size and location of the window aperture.

5.13 Chipset Component Usage Specification

Reliable function and operation of the DLP390TP DMD requires that it be used in conjunction with the other components of the applicable DLP chipset, including those components that contain or implement TI DMD control technology. TI DMD control technology consists of the TI technology and devices used for operating or controlling a DLP DMD.

Note

TI assumes no responsibility for image quality artifacts or DMD failures caused by optical system operating conditions that exceed the limits described previously.

6.3 Feature Description

6.3.1 Power Interface

The DMD requires four DC voltages: 1.8V source (for V_{DD} and V_{DDI}), V_{OFFSET} , V_{RESET} , and V_{BIAS} . In a typical LED-based system, 1.8V, V_{OFFSET} , V_{RESET} , and V_{BIAS} are managed by the DLPA3085 / DLPA3082 PMIC and LED driver.

6.3.2 LPSDR Low-Speed Interface

The low-speed interface handles instructions that configure the DMD and control reset operation. LS_CLK is the low-speed clock, and LS_WDATA is the low-speed data input.

6.3.3 High-Speed Interface

The purpose of the high-speed interface is to transfer pixel data rapidly and efficiently, making use of high-speed DDR transfer and compression techniques to save power and time. The high-speed interface is composed of differential SubLVDS receivers for inputs, with a dedicated clock.

6.3.4 Timing

The data sheet provides timing at the device pin. For output timing analysis, the tester pin electronics and their transmission line effects must be considered. [Figure 5-14](#) shows an equivalent test load circuit for the output under test. Timing reference loads are not intended to be precise representations of any particular system environment or depiction of the actual load presented by a production test. System designers should use IBIS or other simulation tools to correlate the timing reference load to a system environment. The load capacitance value stated is only for the characterization and measurement of AC timing signals. This load capacitance value does not indicate the maximum load the device is capable of driving.

6.4 Device Functional Modes

DMD functional modes are controlled by the DLPC8445V display controller. See the DLPC8445V display controller data sheet or contact a TI applications engineer.

6.5 Optical Interface and System Image Quality Considerations

TI assumes no responsibility for end-equipment optical performance. Achieving the desired end-equipment optical performance involves making trade-offs between numerous component and system design parameters. Optimizing system optical performance and image quality strongly relate to optical system design parameter trade-offs. Although it is not possible to anticipate every conceivable application, projector image quality and optical performance are contingent on compliance with the optical system operating conditions described in the following sections.

6.5.1 Numerical Aperture and Stray Light Control

The angle defined by the numerical aperture of the illumination and projection optics at the DMD optical area should be the same. This angle should not exceed the nominal device micromirror tilt angle unless appropriate apertures are added in the illumination and projection pupils to block out flat-state and stray light from the projection lens. The micromirror tilt angle defines the DMD's capability to separate the "ON" optical path from any other light path, including undesirable flat-state specular reflections from the DMD window, DMD border structures, or other system surfaces near the DMD, such as prism or lens surfaces. If the numerical aperture exceeds the micromirror tilt angle, or if the projection numerical aperture angle is more than two degrees larger than the illumination numerical aperture angle (and vice versa), contrast degradation and objectionable artifacts in the display border and active area could occur.

6.5.2 Pupil Match

TI's optical and image quality specifications assume that the exit pupil of the illumination optics is nominally centered within 2° of the entrance pupil of the projection optics. Misalignment of pupils can create objectionable artifacts in the display border or active area, which may require additional system apertures to control, especially if the numerical aperture of the system exceeds the pixel tilt angle.

6.5.3 Illumination Overfill

The active area of the device is surrounded by an aperture on the inside DMD window surface that masks structures of the DMD chip assembly from normal view and is sized to anticipate several optical operating conditions. Overfill light illuminating the window aperture can create artifacts from the edge of the window aperture opening and other surface anomalies that may be visible on the screen. The illumination optical system should be designed to limit light flux incident anywhere on the window aperture from exceeding approximately 10% of the average flux level in the active area. Depending on the particular system optical architecture, the overfill light on the window aperture may have to be further reduced below the suggested maximum 10% level in order to be acceptable.

6.6 Micromirror Array Temperature Calculation

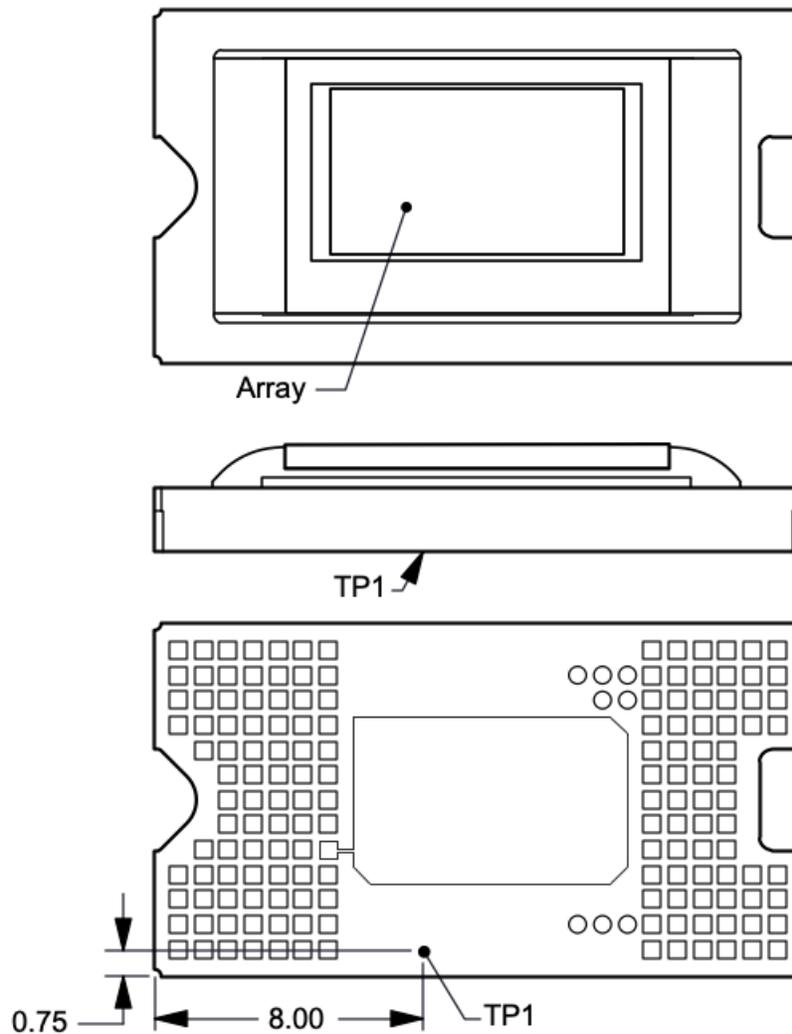


Figure 6-2. DMD Thermal Test Points

Micromirror array temperature cannot be measured directly, therefore, it must be computed analytically from measurement points on the outside of the package, the package thermal resistance, the electrical power, and the illumination heat load. The relationship between array temperature and the reference ceramic temperature (thermal test TP1 in [Figure 6-2](#)) is provided by the following equations:

$$T_{\text{ARRAY}} = T_{\text{CERAMIC}} + (Q_{\text{ARRAY}} \times R_{\text{ARRAY-TO-CERAMIC}})$$

$$Q_{\text{ARRAY}} = Q_{\text{ELECTRICAL}} + Q_{\text{ILLUMINATION}}$$

where

- T_{ARRAY} = Computed array temperature (°C)
- T_{CERAMIC} = Measured ceramic temperature (°C) (TP1 location)
- $R_{\text{ARRAY-TO-CERAMIC}}$ = Thermal resistance of the package specified in [Section 5.5](#) from array to ceramic TP1 (°C/Watt)
- Q_{ARRAY} = Total (electrical + absorbed) DMD power on the array (Watts)
- $Q_{\text{ELECTRICAL}}$ = Nominal electrical power (Watts)
- Q_{INCIDENT} = Incident illumination optical power (Watts)
- DMD average thermal absorptivity = $(0.5559 \times OV_{\text{ILL}}) + 0.448 = 0.5397$
- $Q_{\text{ILLUMINATION}}$ = (DMD average thermal absorptivity \times Q_{INCIDENT}) (Watts)

The electrical power dissipation of the DMD is variable and depends on the voltages, data rates, and operating frequencies. A nominal electrical power dissipation to use when calculating array temperature is 0.5W. The absorbed power from the illumination source is variable and depends on the operating state of the micromirrors and the intensity of the light source. The equations shown above are valid for a single-chip or multichip DMD system.

The sample calculation for a typical projection application is as follows:

$$Q_{\text{INCIDENT}} = 5.8 \text{ W (measured)} \tag{1}$$

$$T_{\text{CERAMIC}} = 55.0 \text{ °C (measured)} \tag{2}$$

$$OV_{\text{ILL}} = 16.3\% \tag{3}$$

$$Q_{\text{ELECTRICAL}} = 0.5 \text{ W} \tag{4}$$

$$\text{DMD average thermal absorptivity} = (0.5559 \times 0.163) + 0.4481 \tag{5}$$

$$Q_{\text{ARRAY}} = 0.5 \text{ W} + (0.5397 \text{ W/Im} \times 5.8 \text{ W}) = 3.62 \text{ W} \tag{6}$$

$$T_{\text{ARRAY}} = 55.0 \text{ °C} + (3.62 \text{ W} \times 2^{\circ}\text{C/W}) = 62.2 \text{ °C} \tag{7}$$

6.7 Micromirror Power Density Calculation

The calculation of the optical power density of the illumination on the DMD in the different wavelength bands uses the total measured optical power on the DMD, percent illumination overfill, area of the active array, and ratio of the spectrum in the wavelength band of interest to the total spectral optical power.

- $ILL_{\text{UV}} = [OP_{\text{UV-RATIO}} \times Q_{\text{INCIDENT}}] \times 1000\text{mW/W} \div A_{\text{ILL}}$ (mW/cm²)
- $ILL_{\text{VIS}} = [OP_{\text{VIS-RATIO}} \times Q_{\text{INCIDENT}}] \div A_{\text{ILL}}$ (W/cm²)
- $ILL_{\text{IR}} = [OP_{\text{IR-RATIO}} \times Q_{\text{INCIDENT}}] \times 1000\text{mW/W} \div A_{\text{ILL}}$ (mW/cm²)
- $ILL_{\text{BLU}} = [OP_{\text{BLU-RATIO}} \times Q_{\text{INCIDENT}}] \div A_{\text{ILL}}$ (W/cm²)
- $ILL_{\text{BLU1}} = [OP_{\text{BLU1-RATIO}} \times Q_{\text{INCIDENT}}] \div A_{\text{ILL}}$ (W/cm²)
- $A_{\text{ILL}} = A_{\text{ARRAY}} \div (1 - OV_{\text{ILL}})$ (cm²)

where:

- ILL_{UV} = UV illumination power density on the DMD (mW/cm^2)
- ILL_{VIS} = VIS illumination power density on the DMD (W/cm^2)
- ILL_{IR} = IR illumination power density on the DMD (mW/cm^2)
- ILL_{BLU} = BLU illumination power density on the DMD (W/cm^2)
- ILL_{BLU1} = BLU1 illumination power density on the DMD (W/cm^2)
- A_{ILL} = illumination area on the DMD (cm^2)
- $Q_{INCIDENT}$ = total incident optical power on DMD (W) (measured)
- A_{ARRAY} = area of the array (cm^2) (data sheet)
- OV_{ILL} = percent of total illumination on the DMD outside the array (%) (optical model)
- $OP_{UV-RATIO}$ = ratio of the optical power for wavelengths $<410nm$ to the total optical power in the illumination spectrum (spectral measurement)
- $OP_{VIS-RATIO}$ = ratio of the optical power for wavelengths $\geq 410nm$ and $\leq 800nm$ to the total optical power in the illumination spectrum (spectral measurement)
- $OP_{IR-RATIO}$ = ratio of the optical power for wavelengths $>800nm$ to the total optical power in the illumination spectrum (spectral measurement)
- $OP_{BLU-RATIO}$ = ratio of the optical power for wavelengths $\geq 410nm$ and $\leq 475nm$ to the total optical power in the illumination spectrum (spectral measurement)
- $OP_{BLU1-RATIO}$ = ratio of the optical power for wavelengths $\geq 410nm$ and $\leq 445nm$ to the total optical power in the illumination spectrum (spectral measurement)

The illumination area varies and depends on the illumination overfill. The total illumination area on the DMD is the array area and the overfill area around the array. The optical model is used to determine the percent of the total illumination on the DMD that is outside the array (OV_{ILL}) and the percent of the total illumination that is on the active array. From these values, the illumination area (A_{ILL}) is calculated. The illumination is assumed to be uniform across the entire array.

From the measured illumination spectrum, the ratio of the optical power in the wavelength bands of interest to the total optical power is calculated.

Sample calculation:

$$Q_{INCIDENT} = 5.8 \text{ W (measured)}$$

$$A_{ARRAY} = ((8.7072 \text{ mm} \times 4.9184 \text{ mm}) \div 100mm^2/cm^2) = 0.4283 \text{ cm}^2 \text{ (data sheet)}$$

$$OV_{ILL} = 16.3\% \text{ (optical model)}$$

$$OP_{UV-RATIO} = 0.00021 \text{ (spectral measurement)}$$

$$OP_{VIS-RATIO} = 0.99977 \text{ (spectral measurement)}$$

$$OP_{IR-RATIO} = 0.00002 \text{ (spectral measurement)}$$

$$OP_{BLU-RATIO} = 0.28100 \text{ (spectral measurement)}$$

$$OP_{BLU1-RATIO} = 0.03200 \text{ (spectral measurement)}$$

$$A_{ILL} = 0.4283 \text{ cm}^2 \div (1 - 0.163) = 0.5117 \text{ cm}^2$$

$$ILL_{UV} = [0.00021 \times 5.8 \text{ W}] \times 1000\text{mW/W} \div 0.5117 \text{ cm}^2 = 2.381 \text{ mW/cm}^2$$

$$ILL_{VIS} = [0.99977 \times 5.8 \text{ W}] \div 0.5117 \text{ cm}^2 = 11.33 \text{ W/cm}^2$$

$$ILL_{IR} = [0.00002 \times 5.8 \text{ W}] \times 1000\text{mW/W} \div 0.5117 \text{ cm}^2 = 0.227 \text{ mW/cm}^2$$

$$ILL_{BLU} = [0.28100 \times 5.8 \text{ W}] \div 0.5117 \text{ cm}^2 = 3.19 \text{ W/cm}^2$$

$$ILL_{BLU1} = [0.03200 \times 5.8 \text{ W}] \div 0.5117 \text{ cm}^2 = 0.36 \text{ W/cm}^2$$

6.8 Window Aperture Illumination Overfill Calculation

The amount of optical overfill on the critical area of the window aperture cannot be measured directly. For systems with uniform illumination on the array, the amount is determined using the total measured incident optical power on the DMD, and the ratio of the total optical power on the DMD that is on the defined critical area. The optical model is used to determine the percentage of optical power on the window aperture critical area and estimate the size of the area.

$$Q_{AP-ILL} = [Q_{INCIDENT} \times OP_{AP_ILL_RATIO}] \div [A_{AP_ILL} \times OP_{CA_RATIO}] (\text{W/cm}^2)$$

where:

- Q_{AP-ILL} = window aperture illumination overfill (W/cm^2)
- $Q_{INCIDENT}$ = total incident optical power on the DMD (Watts) (measured)
- $OP_{AP_ILL_RATIO}$ = ratio of the optical power on the critical area of the window aperture to the total optical power on the DMD (optical model)
- A_{AP-ILL} = size of the window aperture critical area (cm^2) (data sheet)
- OP_{CA_RATIO} = percent of the window aperture critical area with incident optical power (%) (optical model)

Sample calculation:

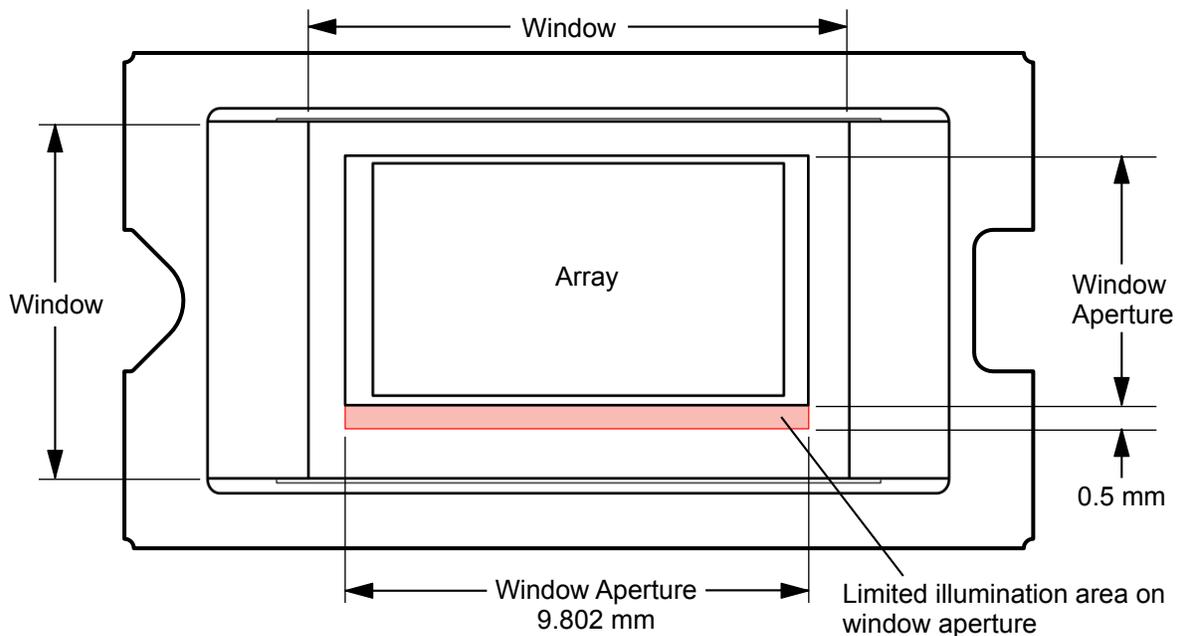


Figure 6-3. Window Aperture Overfill Example

See the above figure for the length of the critical aperture.

$$Q_{\text{INCIDENT}} = 5.8 \text{ W (measured)} \quad (8)$$

$$OP_{\text{AP_ILL_RATIO}} = 0.312\% \text{ (optical model)} \quad (9)$$

$$OV_{\text{CA_RATIO}} = 25\% \text{ (optical model)} \quad (10)$$

$$\text{Length of the window aperture for critical area} = 0.9802 \text{ cm (data sheet)} \quad (11)$$

$$\text{Width of critical area} = 0.050 \text{ cm (data sheet)} \quad (12)$$

$$A_{\text{AP-ILL}} = 0.9802 \text{ cm} \times 0.050 \text{ cm} = 0.04901 \text{ cm}^2 \quad (13)$$

$$Q_{\text{AP-ILL}} = (5.8 \text{ W} \times 0.00312) \div (0.04901 \text{ cm}^2 \times 0.25) = 1.48 \text{ W/cm}^2 \text{ (W/cm}^2\text{)} \quad (14)$$

6.9 Micromirror Landed-On/Landed-Off Duty Cycle

6.9.1 Definition of Micromirror Landed-On/Landed-Off Duty Cycle

The micromirror landed-on/landed-off duty cycle (landed duty cycle) denotes the percentage of time that an individual micromirror is landed in the ON state versus the amount of time the same micromirror is landed in the OFF state.

For example, a landed duty cycle of 100/0 indicates that the referenced pixel is in the ON state 100% of the time (and in the OFF state 0% of the time); whereas 0/100 would indicate that the pixel is in the OFF state 100% of the time. Likewise, 50/50 indicates that the pixel is ON for 50% of the time (and OFF for 50% of the time).

Note that when assessing the landed duty cycle, the time spent switching from one state (ON or OFF) to the other state (OFF or ON) is considered negligible and is thus ignored.

Because a micromirror can only be landed in one state or the other (ON or OFF), the two numbers (percentages) always add to 100.

6.9.2 Landed Duty Cycle and Useful Life of the DMD

Knowing the long-term average landed duty cycle (of the end product or application) is important because subjecting all (or a portion) of the DMD micromirror array (also called the active array) to an asymmetric landed duty cycle for a prolonged period of time can reduce the DMD useful life.

Note that it is the symmetry/asymmetry of the landed duty cycle that is of relevance. The symmetry of the landed duty cycle is determined by how close the two numbers (percentages) are to being equal. For example, a landed duty cycle of 50/50 is exactly symmetrical, whereas a landed duty cycle of 100/0 or 0/100 is exactly asymmetrical.

6.9.3 Landed Duty Cycle and Operational DMD Temperature

Operational DMD temperature and landed duty cycle interact to affect DMD useful life, and this interaction can be exploited to reduce the impact that an asymmetrical landed duty cycle has on the DMD's useful life. This is quantified in the derating curve shown in the *Recommended Operating Conditions*. The importance of this curve is that:

- All points along this curve represent the same useful life.
- All points above this curve represent a lower useful life (and the further away from the curve, the lower the useful life).
- All points below this curve represent a higher useful life (and the further away from the curve, the higher the useful life).

This curve specifies the maximum operating DMD temperature that the DMD should be operated at for a given long-term average landed duty cycle.

6.9.4 Estimating the Long-Term Average Landed Duty Cycle of a Product or Application

During a given period of time, the landed duty cycle of a given pixel follows from the image content being displayed by that pixel.

For example, in the simplest case, when displaying pure-white on a given pixel for a given time period, that pixel operates under a 100/0 landed duty cycle during that time period. Likewise, when displaying pure-black, the pixel operates under a 0/100 landed duty cycle.

Between the two extremes (ignoring, for the moment, color and any image processing that may be applied to an incoming image), the landed duty cycle tracks one-to-one with the grayscale value, as shown in [Table 6-1](#).

Table 6-1. Grayscale Value and Landed Duty Cycle

GRAYSCALE VALUE	LANDED DUTY CYCLE
0%	0/100
10%	10/90
20%	20/80
30%	30/70
40%	40/60
50%	50/50
60%	60/40
70%	70/30
80%	80/20
90%	90/10
100%	100/0

Accounting for color rendition (but still ignoring image processing) requires knowing both the color intensity (from 0% to 100%) for each constituent primary color (red, green, and/or blue) for the given pixel as well as the color cycle time for each primary color, where “color cycle time” is the total percentage of the frame time that a given primary must be displayed in order to achieve the desired white point.

Use [Equation 15](#) to calculate the landed duty cycle of a given pixel during a given time period.

$$\text{Landed Duty Cycle} = (\text{Red_Cycle_}\% \times \text{Red_Scale_Value}) + (\text{Green_Cycle_}\% \times \text{Green_Scale_Value}) + (\text{Blue_Cycle_}\% \times \text{Blue_Scale_Value}) \tag{15}$$

where

- Red_Cycle_%, represents the percentage of the frame time that red is displayed to achieve the desired white point.
- Green_Cycle_% represents the percentage of the frame time that green is displayed to achieve the desired white point.
- Blue_Cycle_%, represents the percentage of the frame time that blue is displayed to achieve the desired white point.

For example, assume that the red, green, and blue color cycle times are 30%, 50%, and 20%, respectively (in order to achieve the desired white point), then the landed duty cycle for various combinations of red, green, blue color intensities would be as shown in [Table 6-2](#) and [Table 6-3](#).

Table 6-2. Example Landed Duty Cycle for Full-Color, Color Percentage

CYCLE PERCENTAGE		
GREEN	BLUE	RED
50%	20%	30%

Table 6-3. Example Landed Duty Cycle for Full-Color

SCALE VALUE			LANDED DUTY CYCLE
GREEN	BLUE	RED	
0%	0%	0%	0/100
100%	0%	0%	50/50
0%	100%	0%	20/80
0%	0%	100%	30/70
12%	0%	0%	6/94
0%	35%	0%	7/93
0%	0%	60%	18/82
100%	100%	0%	70/30
0%	100%	100%	50/50
100%	0%	100%	80/20
12%	35%	0%	13/87
0%	35%	60%	25/75
12%	0%	60%	24/76
100%	100%	100%	100/0

The last factor to account for in estimating the landed duty cycle is any applied image processing. Within the controller, the gamma function affects the landed duty cycle.

Gamma is a power function of the form $\text{Output_Level} = A \times \text{Input_Level}^{\text{Gamma}}$, where A is a scaling factor that is typically set to 1.

In the controller, gamma is applied to the incoming image data on a pixel-by-pixel basis. A typical gamma factor is 2.2, which transforms the incoming data as shown in [Figure 6-4](#).

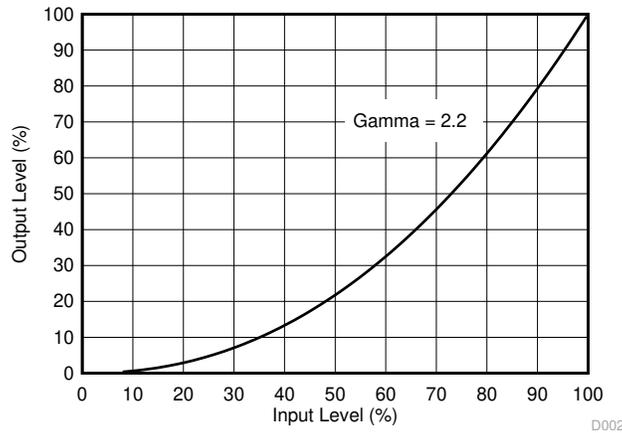


Figure 6-4. Example of Gamma = 2.2

From [Figure 6-4](#), if the grayscale value of a given input pixel is 40% (before gamma is applied), then the grayscale value will be 13% after gamma is applied. Therefore, it can be seen that since gamma has a direct impact on the displayed grayscale level of a pixel, it also has a direct impact on the landed duty cycle of a pixel.

Consideration must also be given to any image processing that occurs before the controller.

7 Application and Implementation

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

7.1 Application Information

DMDs are spatial light modulators that reflect incoming light from an illumination source to one of two directions, with the primary direction being into a projection or collection optic. Each application is derived primarily from the optical architecture of the system and the format of the data coming into the DLPC8445V controller. The high tilt pixel in the bottom-illuminated DMD increases brightness performance and enables a smaller system footprint for thickness-constrained applications. Typical applications using the DLP390TP include mobile smart TVs and digital signage.

DMD power-up and power-down sequencing is strictly controlled by the DLPA3085 / DLPA3082 . Refer to the *Power Supply Recommendations* for power-up and power-down specifications. For reliable operation, the DLP390TP DMD must always be used with the DLPC8445V controller and a DLPA3085 / DLPA3082 PMIC.

7.2 Typical Application

The DLP390TP DMD, combined with DLPC8445V digital controller and a power management device, provides full 4K UHD resolution for bright, colorful display applications. See Figure 7-1, which shows the system components needed along with the LED configuration of the DLP 0.39" 4K UHD chipset. The components include the DLP390TP DMD, the DLPC8445V display controller, and the DLPA3085 / DLPA3082 PMIC and LED driver.

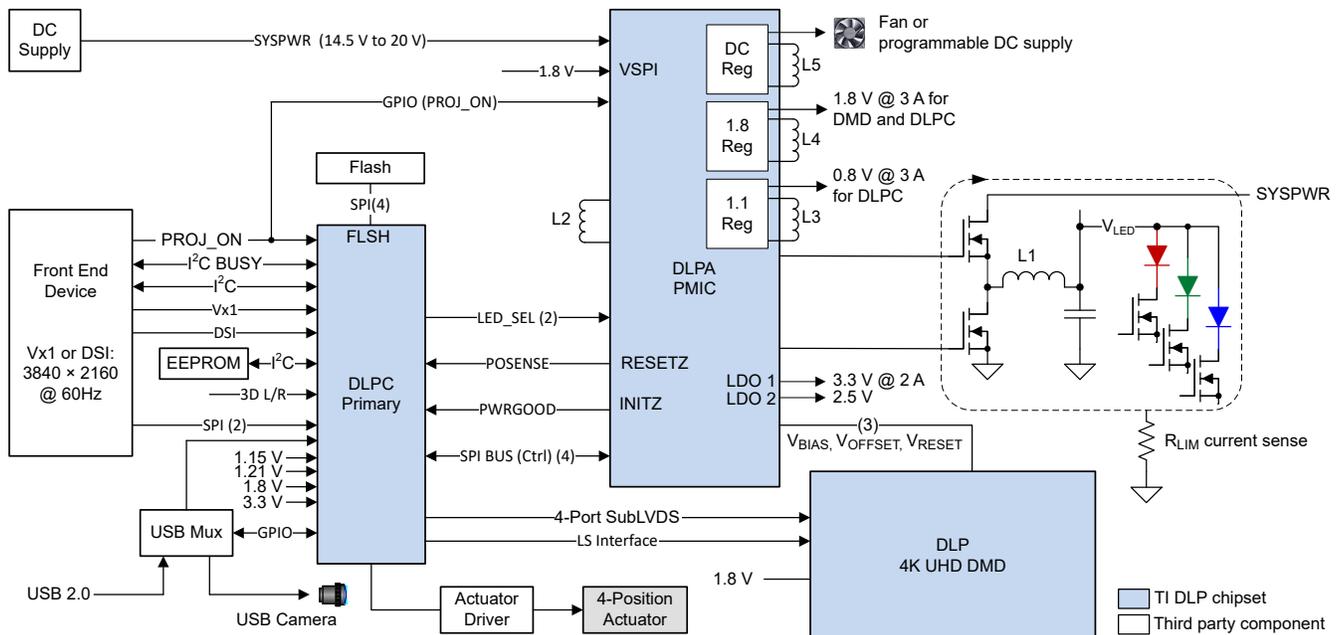


Figure 7-1. Typical 4K UHD LED Application Diagram

7.2.1 Design Requirements

Other core components of the display system include an illumination source, an optical engine for the illumination and projection optics, other electrical and mechanical components, and software. The type of illumination used and the desired brightness have a major effect on the overall system design and size.

The display system uses the DLP390TP as the core imaging device and contains a 0.39" array of micromirrors. The DLPC8445V controller is the digital interface between the DMD and the rest of the system, taking digital input from the front-end receiver and driving the DMD over a high-speed interface. The [DLPA3085 / DLPA3082](#) PMIC serves as a voltage regulator for the DMD, controller, and LED illumination functionality.

7.2.2 Detailed Design Procedure

For a complete DLP system, an optical module or light engine is required that contains the DLP390TP DMD, associated illumination sources, optical elements, and necessary mechanical components.

For reliable operation, use the DMD with the DLPC8445V display controller and the [DLPA3085 / DLPA3082](#) PMIC driver.

7.2.3 Application Curve

The typical LED-current-to-luminance relationship when LED illumination is used is shown in [Figure 7-2](#).

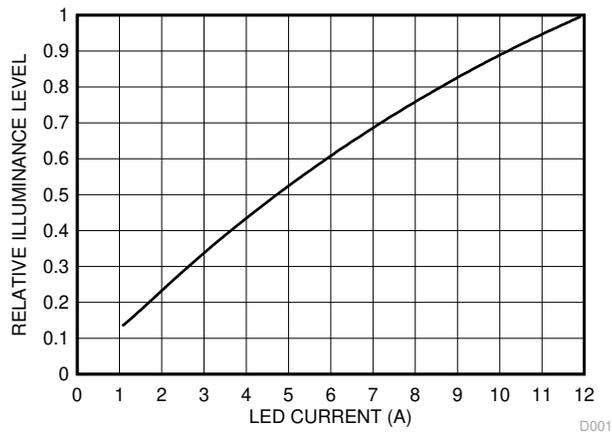


Figure 7-2. Luminance vs Current

7.3 Temperature Sensor Diode

The software application provides functions to configure the [TMP411](#) to read the DLP390TP DMD temperature sensor diode. Use this data to incorporate additional functionality in the overall system design, such as adjusting illumination, fan speeds, and so on. All communication between the [TMP411](#) and the DLPC8445V controller is completed using the I²C interface. The [TMP411](#) connects to the DMD through the pins outlined in [Section 4](#).

8 Power Supply Recommendations

The following power supplies are all required to operate the DMD:

- V_{SS}
- V_{BIAS}
- V_{DD}
- V_{DDI}
- V_{OFFSET}
- V_{RESET}

DMD power-up and power-down sequencing is strictly controlled by the DLP display controller.

CAUTION

For reliable operation of the DMD, the following power supply sequencing requirements must be followed. Failure to adhere to any of the prescribed power-up and power-down requirements may affect device reliability. See the DMD power supply sequencing requirements in [Figure 8-1](#).

V_{BIAS} , V_{DD} , V_{DDI} , V_{OFFSET} , and V_{RESET} power supplies must be coordinated during power-up and power-down operations. Failure to meet any of the requirements below results in a significant reduction in the DMD reliability and lifetime. Common ground V_{SS} must also be connected.

Table 8-1. DMD Power Supply Sequence Requirements

SYMBOL	PARAMETER	DESCRIPTION	MIN	TYP	MAX	UNIT
t_{DELAY1} (1)	Power up delay requirement	from V_{OFFSET} settled at recommended operating voltage to V_{BIAS} and V_{RESET} power up	2			ms
t_{DELAY2} (1)	Power down delay requirement	Delay V_{DD} must be held high from V_{OFFSET} , V_{BIAS} and V_{RESET} powering down.	50			us
V_{OFFSET}	Supply voltage level	at beginning of power-up sequence delay			6	V
V_{BIAS}	Supply voltage level	at end of power-up sequence delay			6	V

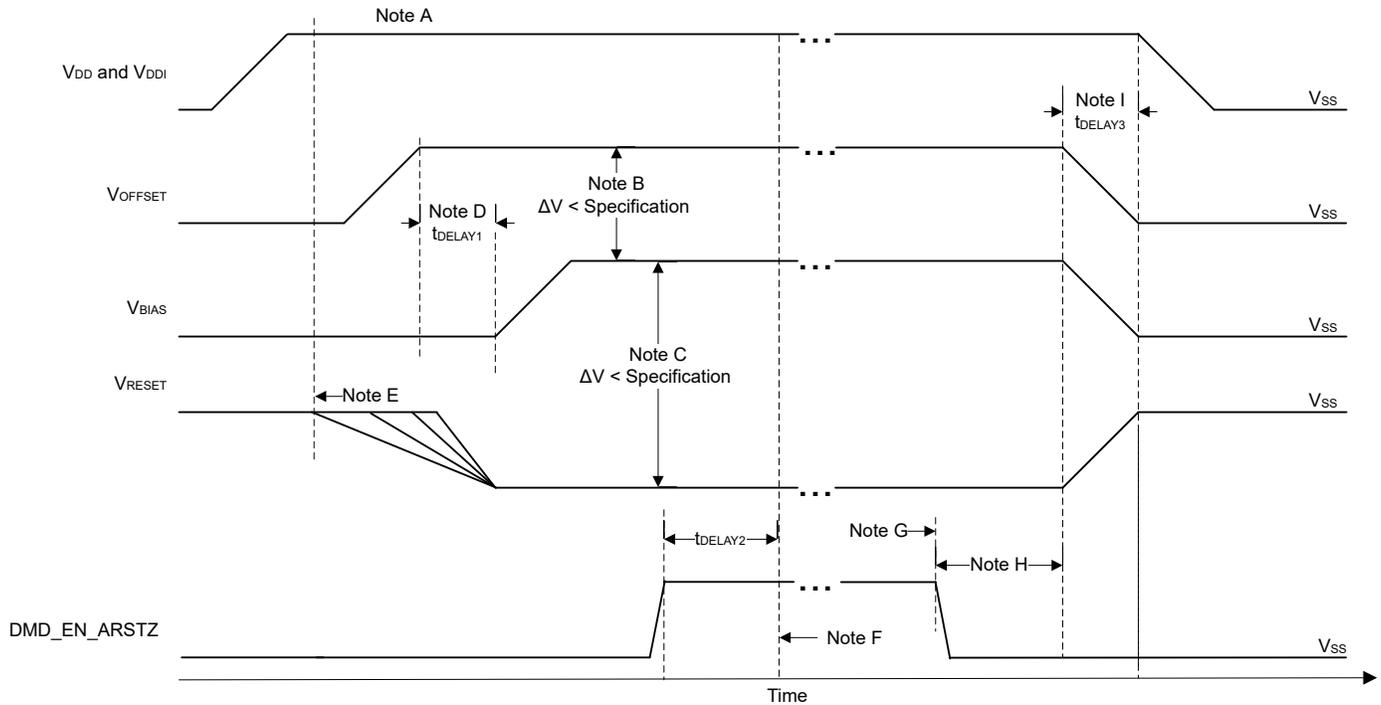
(1) See [Figure 8-1](#).

8.1 DMD Power Supply Power-Up Procedure

- During power-up, V_{DD} and V_{DDI} must always start and settle before V_{OFFSET} plus Delay1, V_{BIAS} , and V_{RESET} voltages are applied to the DMD.
- During power-up, it is a strict requirement that the voltage difference between V_{BIAS} and V_{OFFSET} must be within the specified limit shown in [Section 5.4](#).
- During power-up, there is no requirement for the relative timing of V_{RESET} with respect to V_{BIAS} .
- Power supply slew rates during power-up are flexible, provided that the transient voltage levels follow the requirements specified in [Section 5.1](#), [Section 5.4](#), and in [Figure 8-1](#).
- During power-up, LVCMOS input pins must not be driven high until after V_{DD} have settled at the operating voltages listed in [Section 5.4](#).

8.2 DMD Power Supply Power-Down Procedure

- During power-down, V_{DD} and V_{DDI} must be supplied until after V_{BIAS} , V_{RESET} , and V_{OFFSET} are discharged to within the specified limit of ground.
- During power-down, it is a strict requirement that the voltage difference between V_{BIAS} and V_{OFFSET} must be within the specified limit shown in [Section 5.4](#).
- During power-down, there is no requirement for the relative timing of V_{RESET} with respect to V_{BIAS} .
- Power supply slew rates during power-down are flexible, provided that the transient voltage levels follow the requirements specified in the [Section 5.1](#), [Section 5.4](#), and [Figure 8-1](#).
- During power-down, the LVCMOS input pins must be less than specified in the [Section 5.4](#).



- A. See [Section 4](#) for the *Pin Functions Table*.
- B. To prevent excess current, the supply voltage difference $|V_{\text{OFFSET}} - V_{\text{BIAS}}|$ must be less than the specified limit in the [Section 5.4](#).
- C. To prevent excess current, the supply difference $|V_{\text{BIAS}} - V_{\text{RESET}}|$ must be less than the specified limit in [Section 5.4](#).
- D. V_{BIAS} should power up after V_{OFFSET} has powered up, per the t_{DELAY1} specification.
- E. DLP controller software initiates the global V_{BIAS} command.
- F. After the DMD micromirror park sequence is complete, the DLP controller software initiates a hardware power-down that activates DMD_EN_ARSTZ and disables V_{BIAS}, V_{RESET}, and V_{OFFSET}.
- G. Under power-loss conditions where emergency DMD micromirror park procedures are being enacted by the DLP controller hardware, DMD_EN_ARSTZ will go low.
- H. V_{DD} must remain high until after V_{OFFSET}, V_{BIAS}, and V_{RESET} go low, per the Delay2 specification.
- I. To prevent excess current, the supply voltage delta $|V_{\text{DDI}} - V_{\text{DD}}|$ must be less than the specified limit in [Section 5.4](#).

Figure 8-1. DMD Power Supply Requirements

9 Layout

9.1 Layout Guidelines

The DLP390TP DMD connects to a PCB or a flex circuit using an interposer. For additional layout guidelines regarding length matching and impedance, see the DLPC8445V controller data sheet. For a detailed layout example, refer to the layout design files. Some layout guidelines for routing to the DLP390TP DMD are:

- Match lengths for the LS_WDATA and LS_CLK signals, as specified in the DLPC8445V controller data sheet.
- Match lengths for the HS_bus differential signals as specified in the DLPC8445V controller data sheet.
- Minimize vias, layer changes, and turns for the HS bus signals.
- Supply capacitance needs can vary per design. Refer to the layout design file for a general guideline. Verify all supplies on the design are operating in the recommended operating range at the DMD.

10 Device and Documentation Support

10.1 Third-Party Products Disclaimer

TI'S PUBLICATION OF INFORMATION REGARDING THIRD-PARTY PRODUCTS OR SERVICES DOES NOT CONSTITUTE AN ENDORSEMENT REGARDING THE SUITABILITY OF SUCH PRODUCTS OR SERVICES OR A WARRANTY, REPRESENTATION OR ENDORSEMENT OF SUCH PRODUCTS OR SERVICES, EITHER ALONE OR IN COMBINATION WITH ANY TI PRODUCT OR SERVICE.

10.2 Device Support

10.2.1 Device Nomenclature

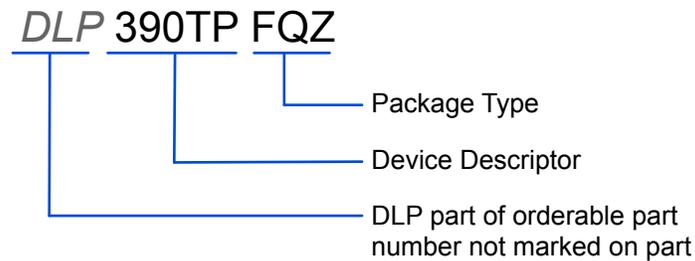


Figure 10-1. Part Number Description

10.2.2 Device Markings

The device marking includes both human-readable information and a 2-dimensional matrix code. The human-readable information is described in [Figure 10-2](#) and includes the legible character string GHJJJK DLP390TPFQZ. GHJJJK is the lot trace code, and DLP390TPFQZ is the device marking.

Example: GHJJJK DLP390TPFQZ

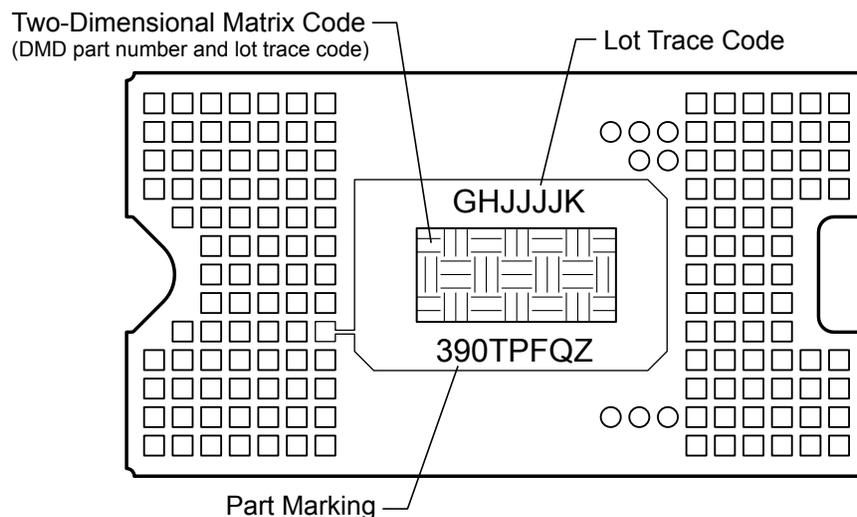


Figure 10-2. DMD Marking Locations

10.3 Documentation Support

10.4 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Notifications* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

10.5 Support Resources

[TI E2E™ support forums](#) are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's [Terms of Use](#).

10.6 Trademarks

TI E2E™ is a trademark of Texas Instruments.

DLP® is a registered trademark of Texas Instruments.

All trademarks are the property of their respective owners.

10.7 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

10.8 Glossary

[TI Glossary](#) This glossary lists and explains terms, acronyms, and definitions.

11 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

DATE	REVISION	NOTES
February 2026	*	Initial Release

12 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
DLP390TPFQZ	Active	Production	CLGA (FQZ) 159	96 JEDEC TRAY (5+1)	Yes	NIAU	N/A for Pkg Type	0 to 70	

(1) **Status:** For more details on status, see our [product life cycle](#).

(2) **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

(4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

8

7

6

5

4

3

DWG NO. 2518600

SH 2

1

D

D

C

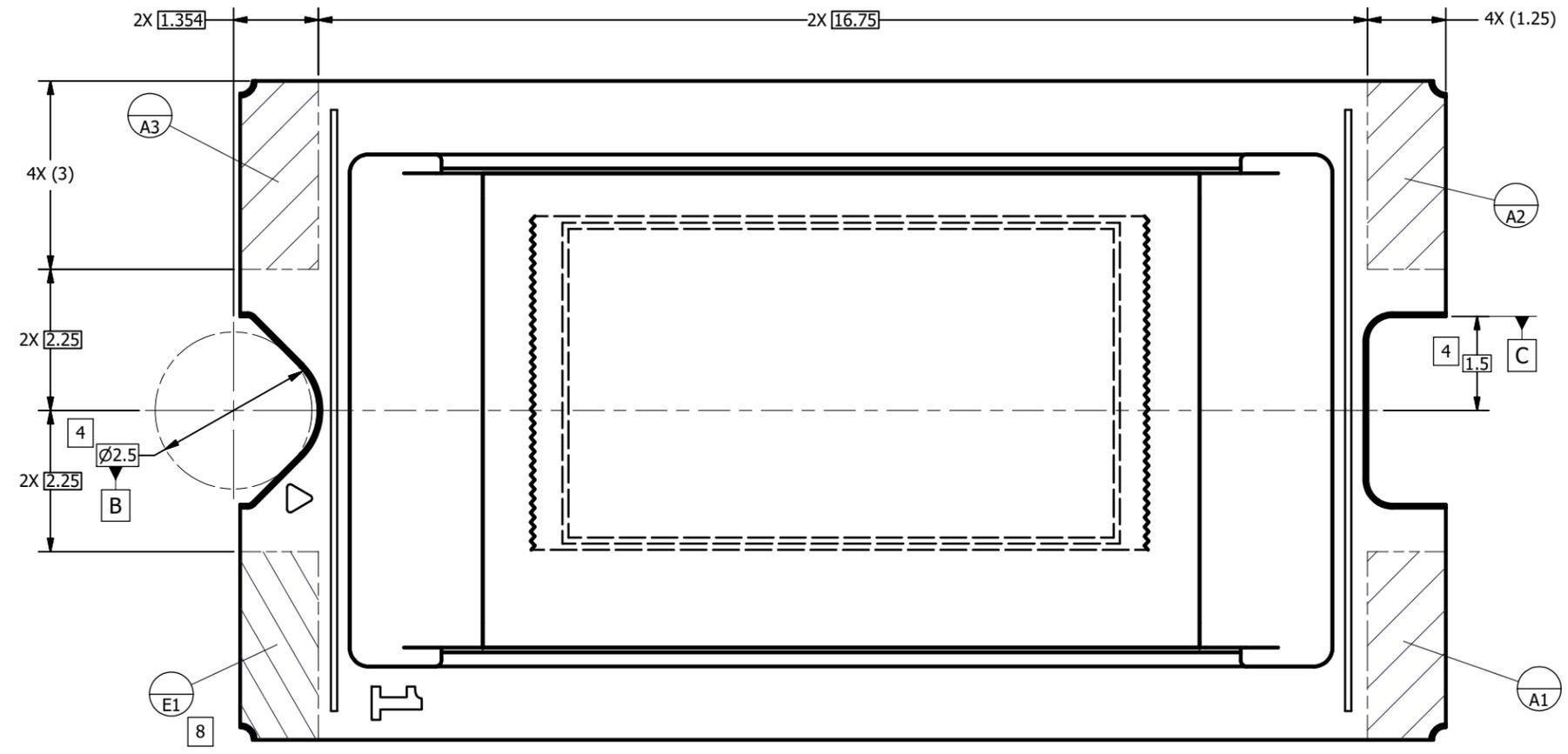
C

B

B

A

A



VIEW C
 DATUMS A AND E
 SCALE 20 : 1
 (FROM SHEET 1)



DRAWN
B. HASKETT

DATE
5/1/2023

SIZE
D

SCALE

DWG NO.
2518600

REV
A

SHEET 2 OF 5

8

7

6

5

4

3

2

1

D

D

C

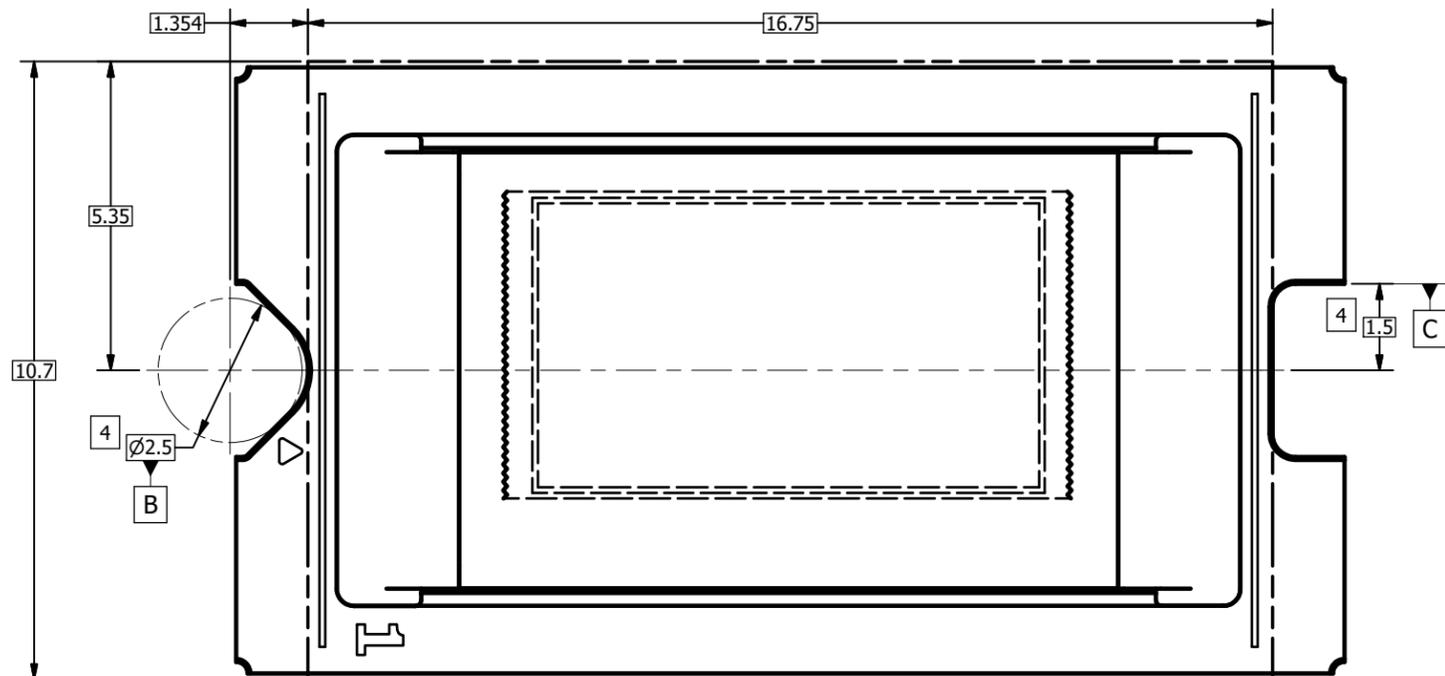
C

B

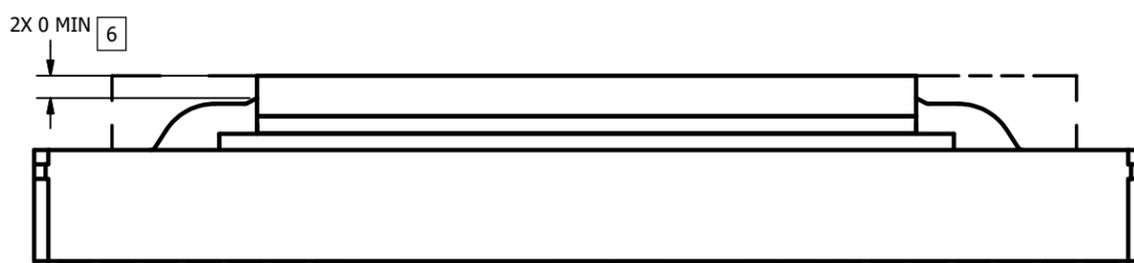
B

A

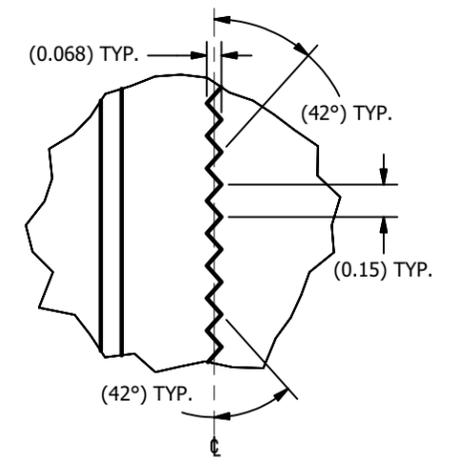
A



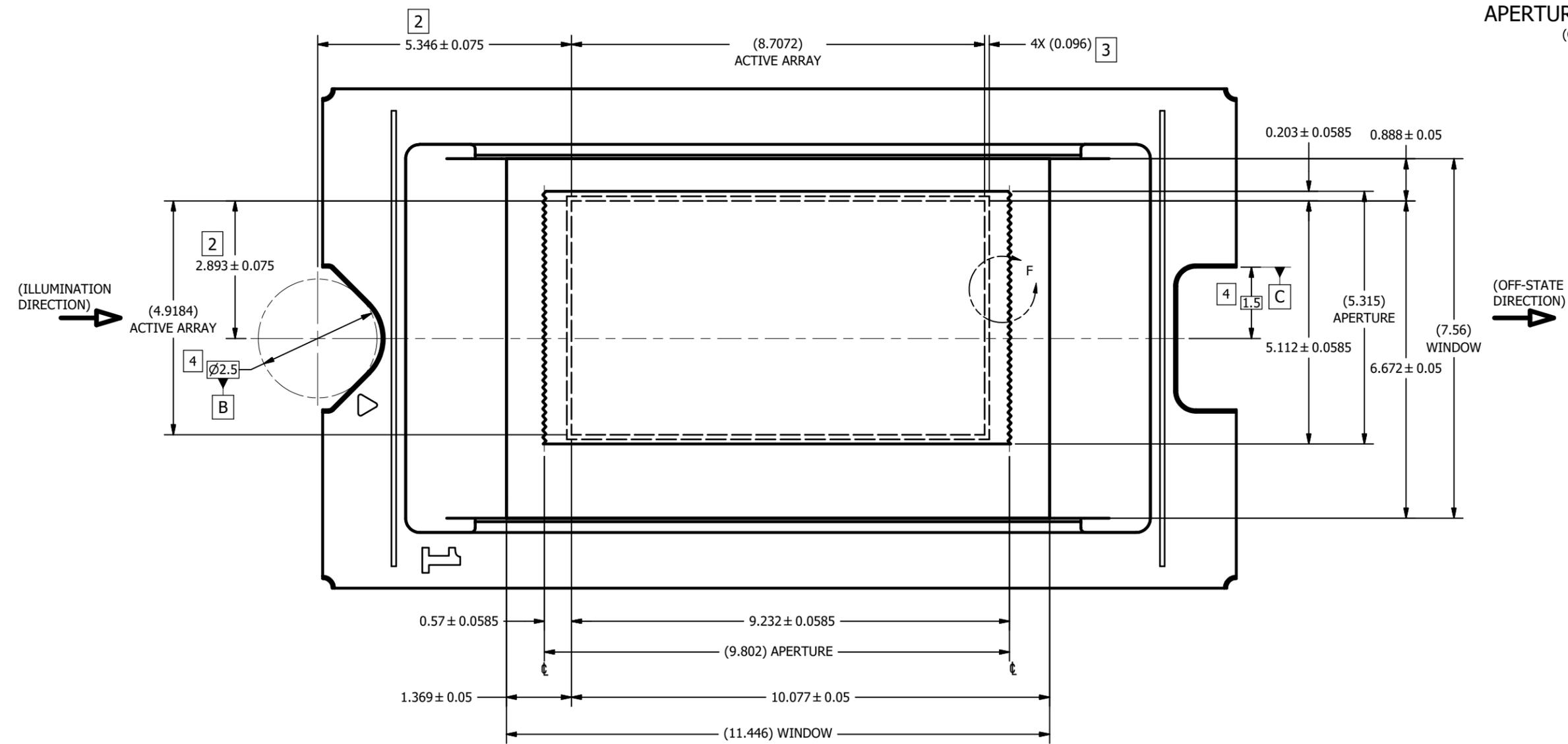
VIEW D
ENCAPSULANT MAXIMUM X/Y DIMENSIONS ⁵
(FROM SHEET 1)



VIEW E
ENCAPSULANT MAXIMUM HEIGHT



DETAIL F
APERTURE LEFT AND RIGHT EDGES
 (GLASS OMITTED FOR CLARITY)
 SCALE 60 : 1



VIEW E
WINDOW AND ACTIVE ARRAY
 SCALE 20 : 1
 (FROM SHEET 1)

 TEXAS INSTRUMENTS <small>Dallas Texas</small>	DRAWN B. HASKETT	DATE 5/1/2023	SIZE D	DWG NO. 2518600	REV A
	SCALE	SHEET 4 OF 5			

D

D

C

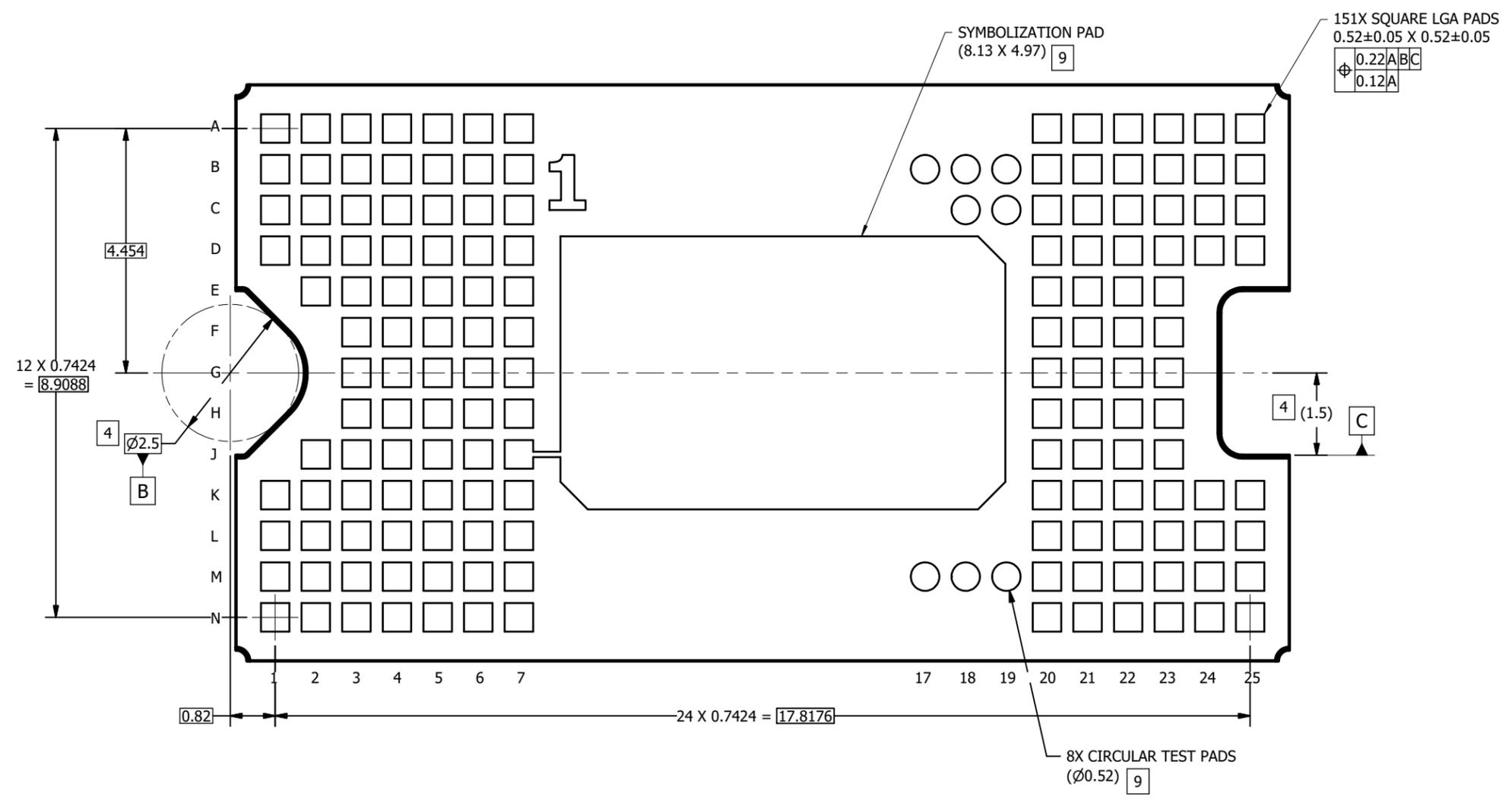
C

B

B

A

A



VIEW H-H
BACK SIDE METALLIZATION
SCALE 20 : 1

IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATASHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, regulatory or other requirements.

These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you fully indemnify TI and its representatives against any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to [TI's Terms of Sale](#), [TI's General Quality Guidelines](#), or other applicable terms available either on [ti.com](#) or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products. Unless TI explicitly designates a product as custom or customer-specified, TI products are standard, catalog, general purpose devices.

TI objects to and rejects any additional or different terms you may propose.

Copyright © 2026, Texas Instruments Incorporated

Last updated 10/2025